

3.2-W/Ch Stereo Class-D Audio Amplifier with Fast Gain Ramp SmartGain™ AGC/DRC

Check for Samples: [TPA2026D2](#)

FEATURES

- **Fast AGC Start-up Time: 5 ms**
- **Pin-Out Compatible with TPA2016D2**
- **Filter-Free Class-D Architecture**
- **3.2 W/Ch Into 4 Ω at 5 V (10% THD+N)**
- **750 mW/Ch Into 8 Ω at 3.6 V (10% THD+N)**
- **Power Supply Range: 2.5 V to 5.5 V**
- **Flexible Operation With/Without I²C**
- **Programmable DRC/AGC Parameters**
- **Digital I²C Volume Control**
- **Selectable Gain from 0 dB to 30 dB in 1-dB Steps**
- **Selectable Attack, Release and Hold Times**
- **4 Selectable Compression Ratios**
- **Low Supply Current: 3.5 mA**
- **Low Shutdown Current: 0.2 μA**
- **High PSRR: 80 dB**
- **AGC Enable/Disable Function**
- **Limiter Enable/Disable Function**
- **Short-Circuit and Thermal Protection**
- **Space-Saving Package**
 - 2,2 mm x 2,2 mm Nano-Free™ WCSP (YZH)

APPLICATIONS

- **Wireless or Cellular Handsets and PDAs**
- **Portable Navigation Devices**
- **Portable DVD Player**
- **Notebook PCs**
- **Portable Radio**
- **Portable Games**
- **Educational Toys**
- **USB Speakers**

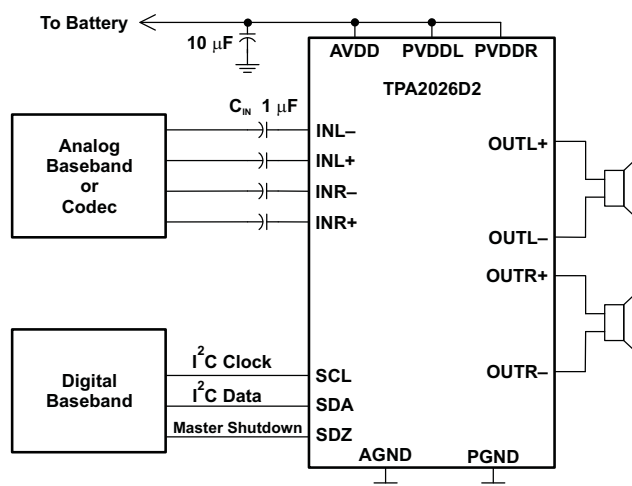
DESCRIPTION

The TPA2026D2 is a stereo, filter-free Class-D audio power amplifier with volume control, dynamic range compression (DRC) and automatic gain control (AGC). It is available in a 2.2 mm x 2.2 mm WCSP package.

The DRC/AGC function in the TPA2026D2 is programmable via a digital I²C interface. The DRC/AGC function can be configured to automatically prevent distortion of the audio signal and enhance quiet passages that are normally not heard. The DRC/AGC can also be configured to protect the speaker from damage at high power levels and compress the dynamic range of music to fit within the dynamic range of the speaker. The gain can be selected from 0 dB to +30 dB in 1-dB steps. The TPA2026D2 is capable of driving 3.2 W/Ch at 5 V into an 4-Ω load or 750 mW/Ch at 3.6 V into an 8-Ω load. The device features independent software shutdown controls for each channel and also provides thermal and short circuit protection. The TPA2026D2 has faster AGC gain ramp during start-up than TPA2026D2.

In addition to these features, a fast start-up time and small package size make the TPA2026D2 an ideal choice for cellular handsets, PDAs, and other portable applications.

SIMPLIFIED APPLICATION DIAGRAM



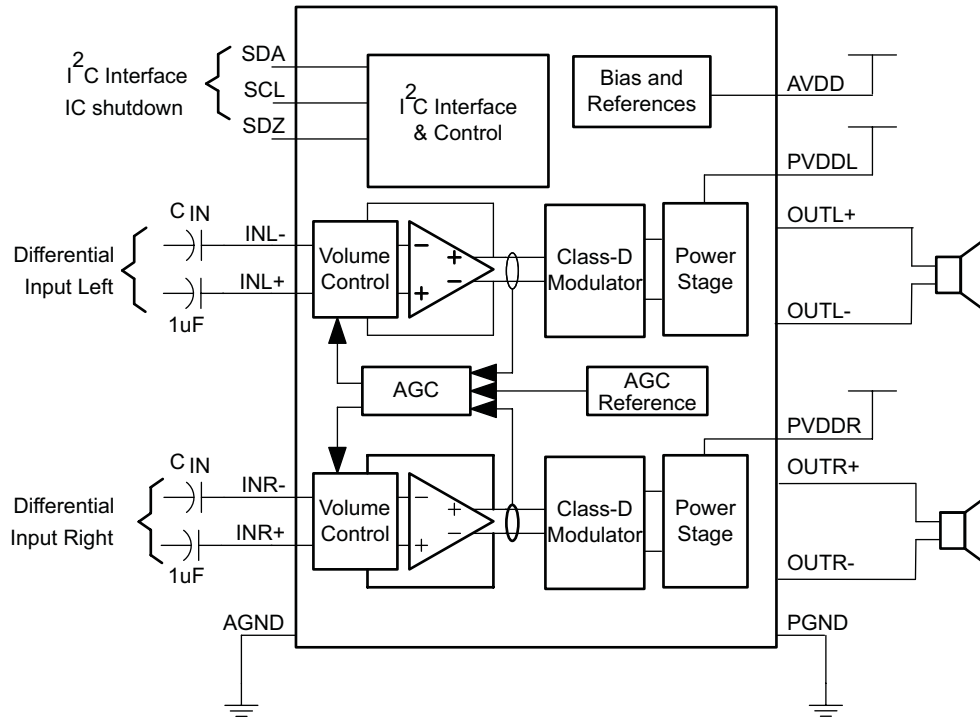
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SmartGain, Nano-Free are trademarks of Texas Instruments.
All other trademarks are the property of their respective owners.



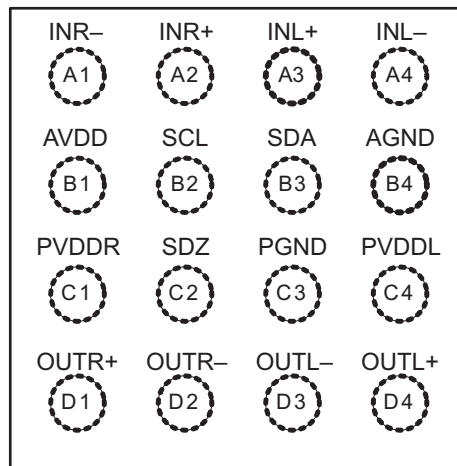
These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



DEVICE PINOUT

**YZH (WCSP) PACKAGE
(Top View)**



PIN FUNCTIONS

PIN		I/O/P	DESCRIPTION
NAME	WCSP		
INR+	A2	I	Right channel positive audio input
INR–	A1	I	Right channel negative audio input
INL+	A3	I	Left channel positive audio input
INL–	A4	I	Left channel negative audio input
SDZ	C2	I	Shutdown terminal (active low)
SDA	B3	I/O	I ² C data interface
SCL	B2	I	I ² C clock interface
OUTR+	D1	O	Right channel positive differential output
OUTR–	D2	O	Right channel negative differential output
OUTL+	D4	O	Left channel positive differential output
OUTL–	D3	O	Left channel negative differential output
AVDD	B1	P	Analog supply (must be the same as PVDDR and PVDDL)
AGND	B4	P	Analog ground (all GND pins need to be connected)
PVDDR	C1	P	Right channel power supply (must be the same as AVDD and PVDDL)
PGND	C3	P	Power ground (all GND pins need to be connected)
PVDDL	C4	P	Left channel power supply (must be the same as AVDD and PVDDR)

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted).

			VALUE / UNIT
V _{DD}	Supply voltage	AVDD, PVDDR, PVDDL	–0.3 V to 6 V
	Input voltage	SDZ, INR+, INR–, INL+, INL–	–0.3 V to V _{DD} +0.3 V
		SDA, SCL	–0.3 V to 6 V
	Continuous total power dissipation		See Dissipation Ratings Table
T _A	Operating free-air temperature range		–40°C to 85°C
T _J	Operating junction temperature range		–40°C to 150°C
T _{stg}	Storage temperature range		–65°C to 150°C
ESD	Electro-static discharge tolerance, all pins	Human body model (HBM)	2 KV
		Charged device model (CDM)	500 V
R _L	Minimum load resistance		3.2 Ω

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS TABLE⁽¹⁾

PACKAGE	T _A ≤ 25°C	DERATING FACTOR	T _A = 70°C	T _A = 85°C
16-ball WCSP	1.25 W	10 mW/°C	0.8 W	0.65 W

(1) Dissipations ratings are for a 2-side, 2-plane PCB.

AVAILABLE OPTIONS⁽¹⁾

T _A	PACKAGED DEVICE ⁽²⁾	PART NUMBER	SYMBOL
-40°C to 85°C	16-ball, 2,2 mm × 2,2 mm WCSP (+0.01 mm/ -0.09 mm tolerance)	TPA2026D2 YZHR	NSV
		TPA2026D2 YZHT	NSV

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com
- (2) The YZH package is only available taped and reeled. The suffix R indicates a reel of 3000; the suffix T indicates a reel of 250.

RECOMMENDED OPERATING CONDITIONS

		MIN	MAX	UNIT	
V _{DD}	Supply voltage	AVDD, PVDDR, PVDDL	2.5	5.5	V
V _{IH}	High-level input voltage	SDZ, SDA, SCL	1.3		V
V _{IL}	Low-level input voltage	SDZ, SDA, SCL		0.6	V
T _A	Operating free-air temperature		-40	+85	°C

ELECTRICAL CHARACTERISTICS

at T_A = 25°C, V_{DD} = 3.6 V, SDZ = 1.3 V, and R_L = 8 Ω + 33 μH (unless otherwise noted).

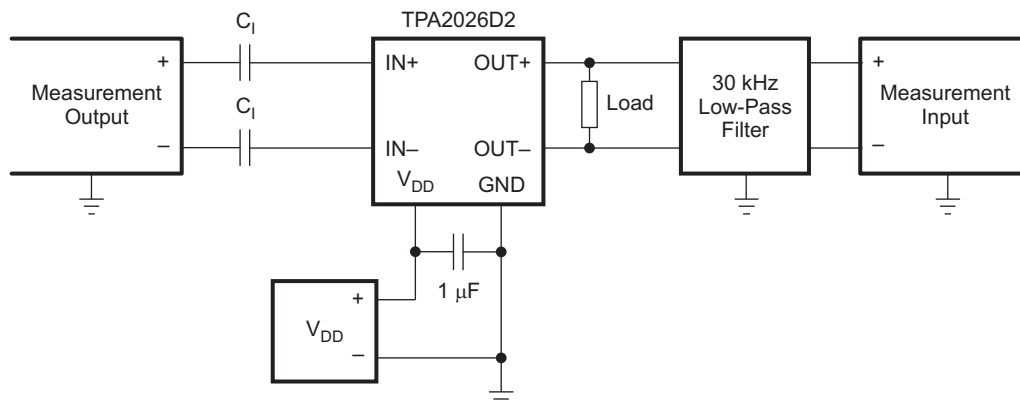
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{DD}	Supply voltage range	2.5	3.6	5.5	V
I _{SDZ}	Shutdown quiescent current	SDZ = 0.35 V, V _{DD} = 2.5 V	0.1	1	μA
		SDZ = 0.35 V, V _{DD} = 3.6 V	0.2	1	
		SDZ = 0.35 V, V _{DD} = 5.5 V	0.3	1	
I _{SWS}	Software shutdown quiescent current	SDZ = 1.3 V, V _{DD} = 2.5 V	35	50	μA
		SDZ = 1.3 V, V _{DD} = 3.6 V	50	70	
		SDZ = 1.3 V, V _{DD} = 5.5 V	75	110	
I _{DD}	Supply current	V _{DD} = 2.5 V	3.5	4.5	mA
		V _{DD} = 3.6 V	3.7	4.7	
		V _{DD} = 5.5 V	4.5	5.5	
f _{SW}	Class D switching frequency	275	300	325	kHz
I _{IH}	High-level input current	V _{DD} = 5.5 V, SDZ = 5.8 V		1	μA
I _{IL}	Low-level input current	V _{DD} = 5.5 V, SDZ = -0.3 V	-1		μA
t _{START}	Start-up time	2.5 V ≤ V _{DD} ≤ 5.5 V no pop, C _{IN} ≤ 1 μF	5		ms
POR	Power on reset ON threshold		2	2.3	V
POR	Power on reset hysteresis		0.2		V
CMRR	Input common mode rejection	R _L = 8 Ω, V _{icm} = 0.5 V and V _{icm} = V _{DD} - 0.8 V, differential inputs shorted	-70		dB
V _{oo}	Output offset voltage	V _{DD} = 3.6 V, A _V = 6 dB, R _L = 8 Ω, inputs ac grounded	2	10	mV
Z _{OUT}	Output impedance in shutdown mode	SDZ = 0.35 V	2		kΩ
	Gain accuracy	Compression and limiter disabled, Gain = 0 to 30 dB	-0.5	0.5	dB
PSRR	Power supply rejection ratio	V _{DD} = 2.5 V to 4.7 V	-80		dB

OPERATING CHARACTERISTICS

at $T_A = 25^\circ\text{C}$, $V_{DD} = 3.6\text{V}$, $SDZ = 1.3\text{V}$, $R_L = 8\ \Omega + 33\ \mu\text{H}$, and $A_V = 6\ \text{dB}$ (unless otherwise noted).

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
k_{SVR}	Power-supply ripple rejection ratio	$V_{DD} = 3.6\text{Vdc}$ with ac of 200mV_{PP} at 217Hz		-68		dB
THD+N	Total harmonic distortion + noise	$f_{\text{aud_in}} = 1\text{kHz}$, $P_O = 550\text{mW}$, $V_{DD} = 3.6\text{V}$		0.1%		
		$f_{\text{aud_in}} = 1\text{kHz}$, $P_O = 1\text{W}$, $V_{DD} = 5\text{V}$		0.1%		
		$f_{\text{aud_in}} = 1\text{kHz}$, $P_O = 630\text{mW}$, $V_{DD} = 3.6\text{V}$		1%		
		$f_{\text{aud_in}} = 1\text{kHz}$, $P_O = 1.4\text{W}$, $V_{DD} = 5\text{V}$		1%		
$N_{f_{nF}}$	Output integrated noise	$A_V = 6\ \text{dB}$		44		μV
$N_{f_{nA}}$	Output integrated noise	$A_V = 6\ \text{dB}$ floor, A-weighted		33		μV
FR	Frequency response	$A_V = 6\ \text{dB}$	20		20000	Hz
$P_{O_{\text{max}}}$	Maximum output power	THD+N = 10%, $V_{DD} = 5\text{V}$, $R_L = 8\ \Omega$		1.72		W
		THD+N = 10%, $V_{DD} = 3.6\text{V}$, $R_L = 8\ \Omega$		750		mW
		THD+N = 1%, $V_{DD} = 5\text{V}$, $R_L = 8\ \Omega$		1.4		W
		THD+N = 1%, $V_{DD} = 3.6\text{V}$, $R_L = 8\ \Omega$		630		mW
η	Efficiency	THD+N = 1%, $V_{DD} = 3.6\text{V}$, $R_L = 8\ \Omega$, $P_O = 0.63\text{W}$		90%		
		THD+N = 1%, $V_{DD} = 5\text{V}$, $R_L = 8\ \Omega$, $P_O = 1.4\text{W}$		90%		

TEST SET-UP FOR GRAPHS



- (1) All measurements were taken with a $1\text{-}\mu\text{F}$ C_1 (unless otherwise noted).
- (2) A $33\text{-}\mu\text{H}$ inductor was placed in series with the load resistor to emulate a small speaker for efficiency measurements.
- (3) The 30-kHz low-pass filter is required, even if the analyzer has an internal low-pass filter. An RC low-pass filter ($1\ \text{k}\Omega$ $4.7\ \text{nF}$) is used on each output for the data sheet graphs.

I²C TIMING CHARACTERISTICS

For I²C Interface Signals Over Recommended Operating Conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
f _{SCL}	Frequency, SCL			400	kHz
t _{W(H)}	Pulse duration, SCL high	0.6			μs
t _{W(L)}	Pulse duration, SCL low	1.3			μs
t _{SU(1)}	Setup time, SDA to SCL	100			ns
t _{h1}	Hold time, SCL to SDA	10			ns
t _(buf)	Bus free time between stop and start condition	1.3			μs
t _{SU2}	Setup time, SCL to start condition	0.6			μs
t _{h2}	Hold time, start condition to SCL	0.6			μs
t _{SU3}	Setup time, SCL to stop condition	0.6			μs

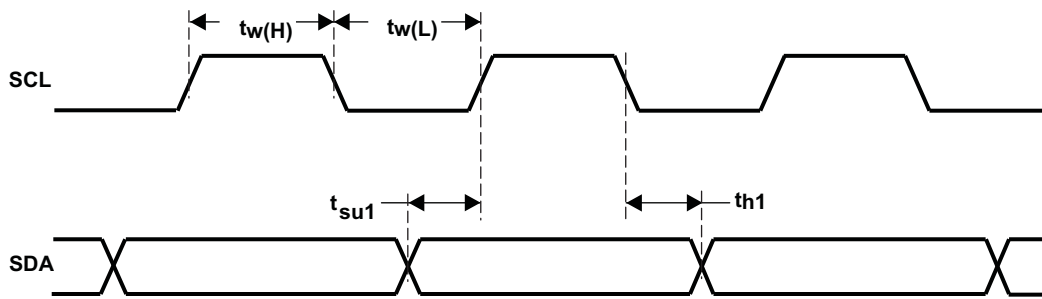


Figure 1. SCL and SDA Timing

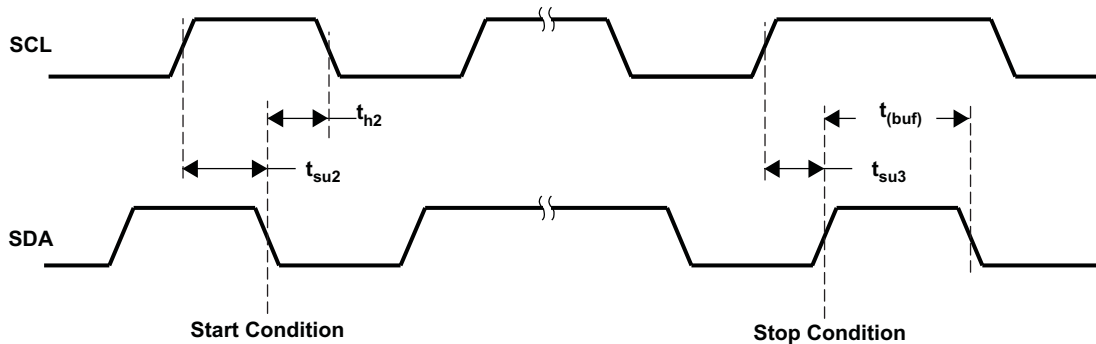


Figure 2. Start and Stop Conditions Timing

TYPICAL CHARACTERISTICS

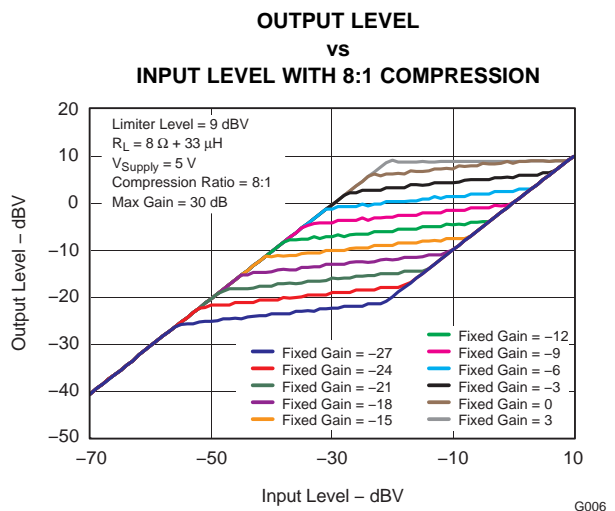
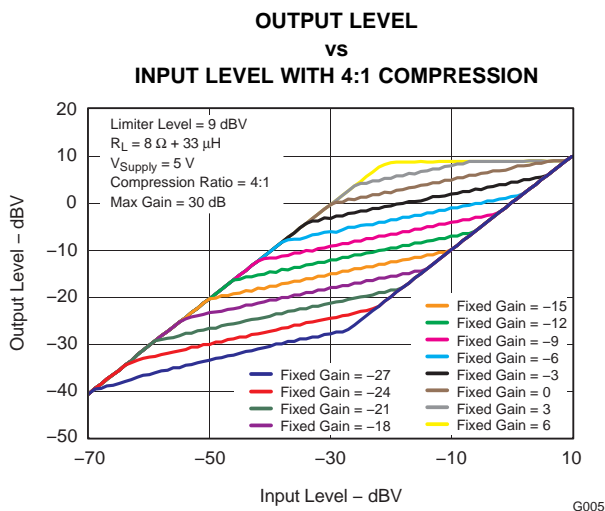
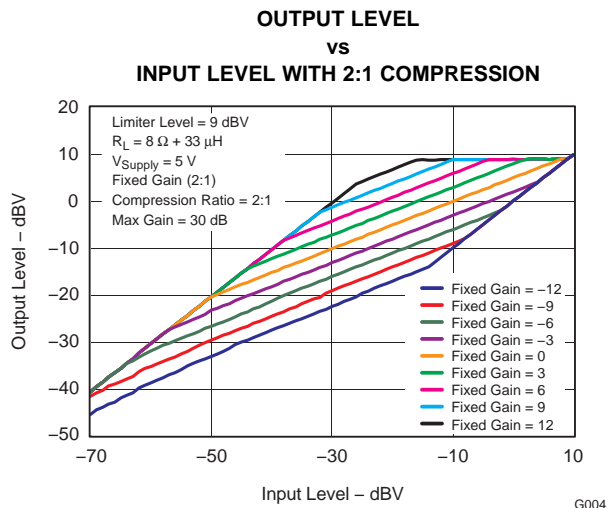
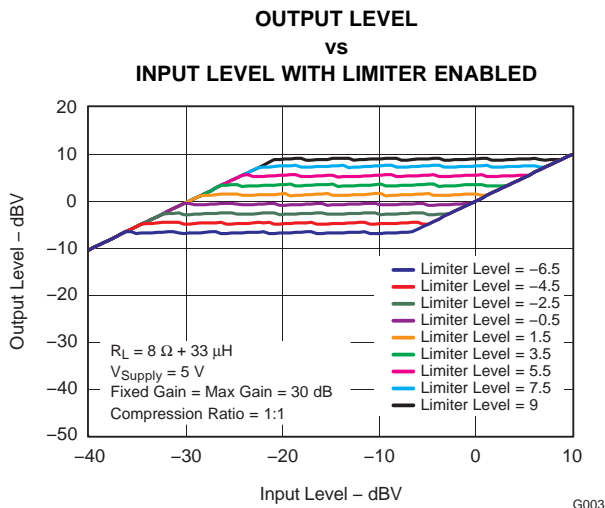
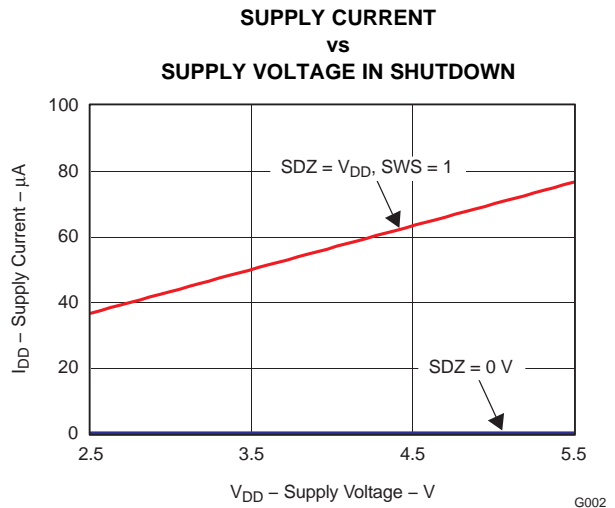
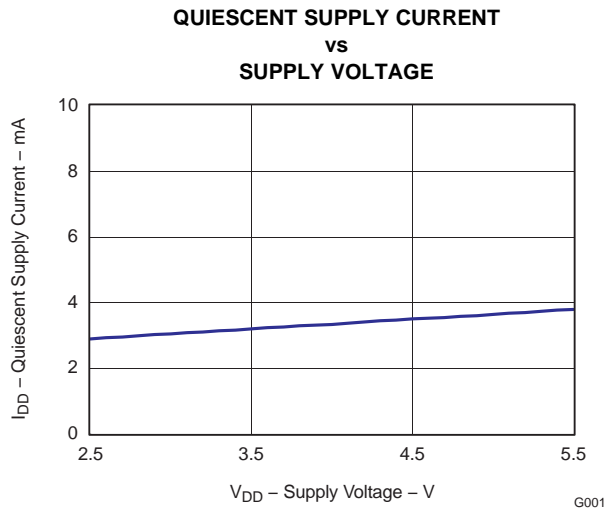
 with $C_{(DECOUPLE)} = 1 \mu\text{F}$, $C_1 = 1 \mu\text{F}$.

All THD + N graphs are taken with outputs out of phase (unless otherwise noted).

All data is taken on left channel.

Table of Graphs

		FIGURE
Quiescent supply current	vs Supply voltage	Figure 3
Supply current	vs Supply voltage in shutdown	Figure 4
Output level	vs Input level	Figure 5
Output level	vs Input level	Figure 6
Output level	vs Input level	Figure 7
Output level	vs Input level	Figure 8
Output level	vs Input level	Figure 9
Supply ripple rejection ratio	vs Frequency, 8Ω	Figure 10
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 2.5\text{V}$, 4Ω	Figure 11
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 2.5\text{V}$, 8Ω	Figure 12
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 3.6\text{V}$, 4Ω	Figure 13
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 3.6\text{V}$, 8Ω	Figure 14
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 5.0\text{V}$, 4Ω	Figure 15
Total harmonic distortion + noise	vs Frequency $V_{\text{supply}} = 5.0\text{V}$, 8Ω	Figure 16
Total harmonic distortion + noise	vs Output power, 4Ω	Figure 17
Total harmonic distortion + noise	vs Output power, 8Ω	Figure 18
Efficiency	vs Output power (per channel), 4Ω	Figure 19
Efficiency	vs Output power (per channel), 8Ω	Figure 20
Total power dissipation	vs Total output power, 4Ω	Figure 21
Total power dissipation	vs Total output power, 8Ω	Figure 22
Total supply current	vs Total output power, 4Ω	Figure 23
Total supply current	vs Total output power, 8Ω	Figure 24
Output power	vs Supply voltage, 4Ω	Figure 25
Output power	vs Supply voltage, 8Ω	Figure 26
TPA2026D2	vs TPA2016D2 Startup gain ramp	Figure 27
TPA2026D2	vs TPA2016D2 Shutdown gain ramp	Figure 28
Shutdown time		Figure 29
Startup time		Figure 30



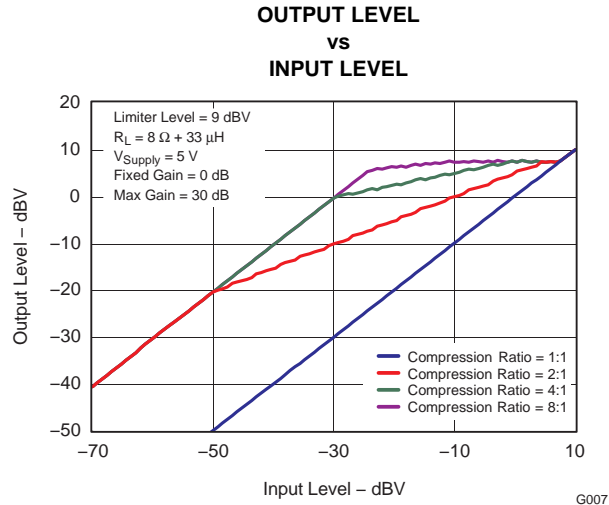


Figure 9.

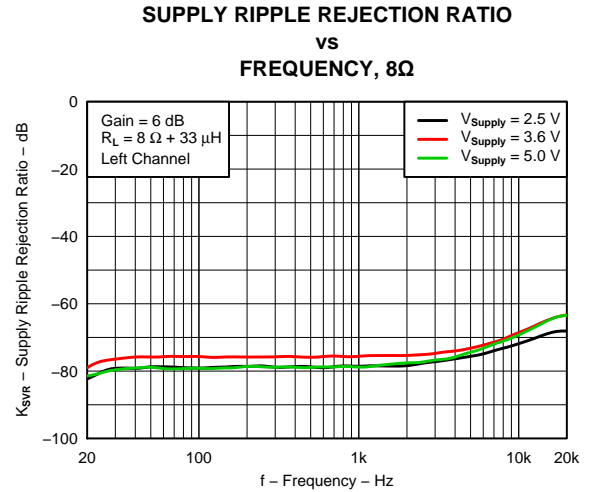


Figure 10.

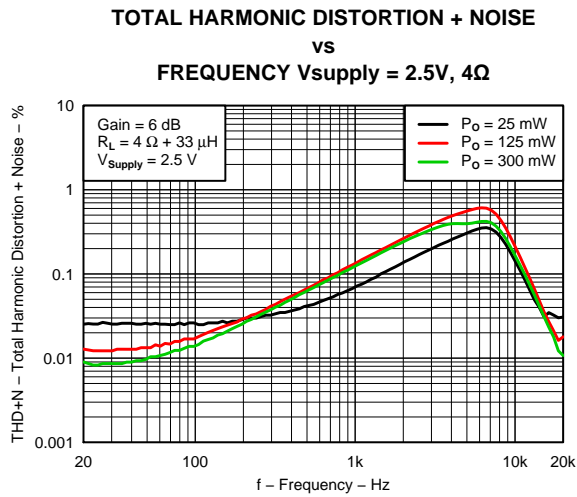


Figure 11.

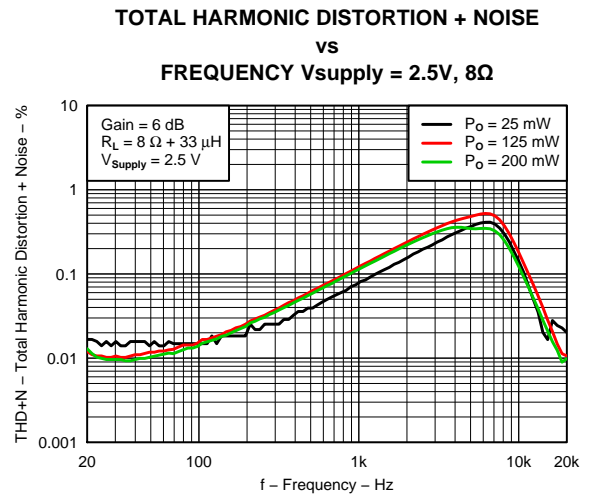


Figure 12.

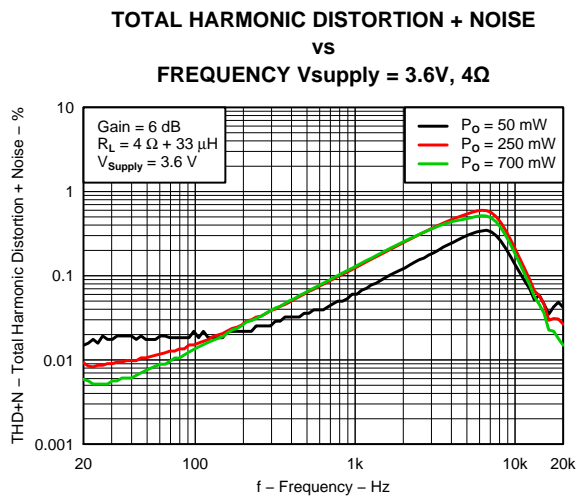


Figure 13.

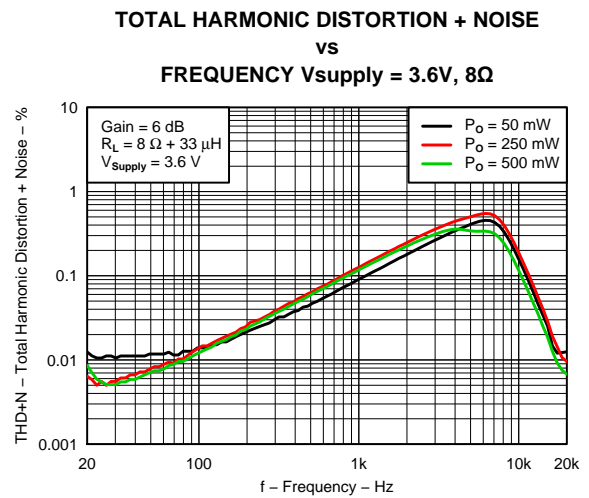


Figure 14.

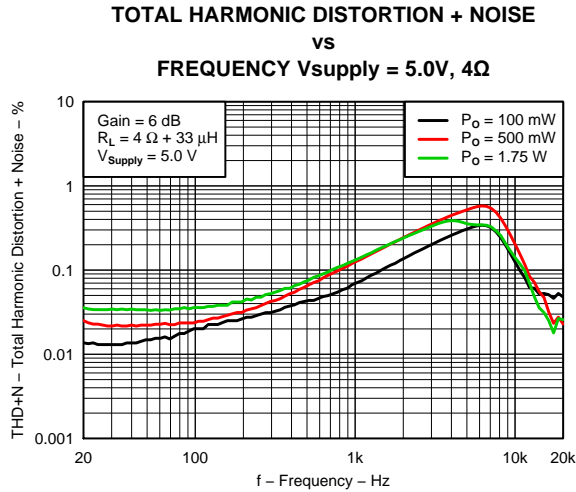


Figure 15.

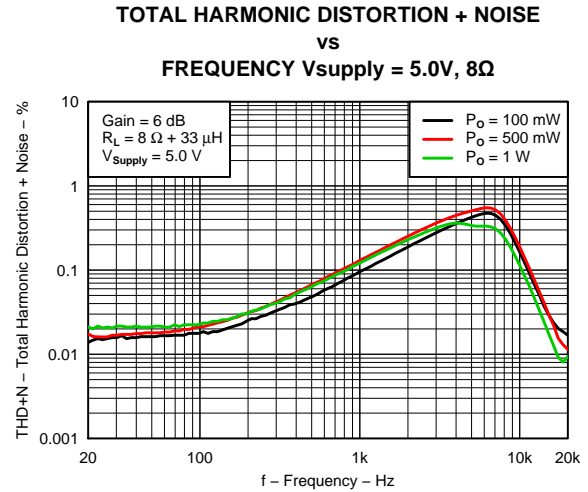


Figure 16.

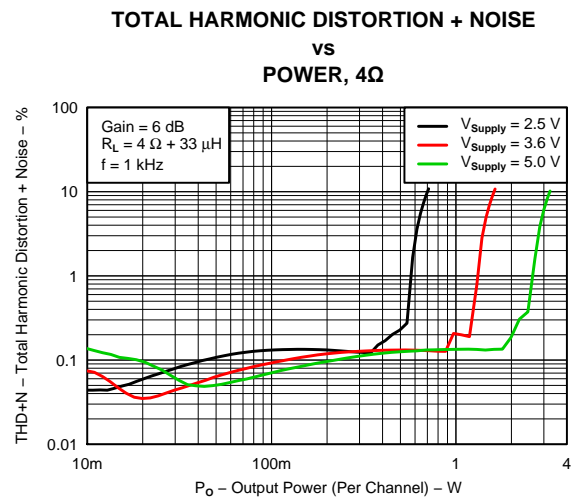


Figure 17.

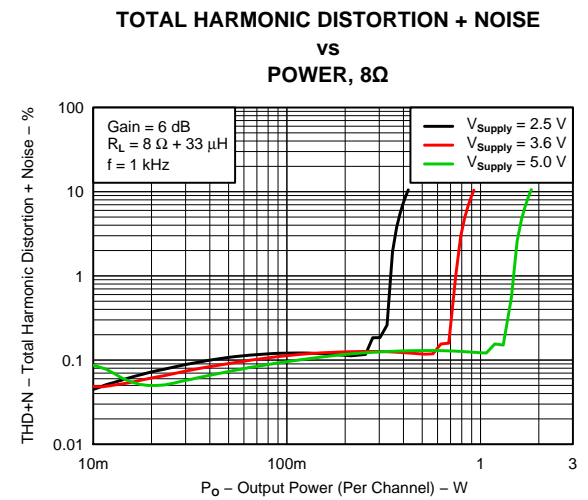


Figure 18.

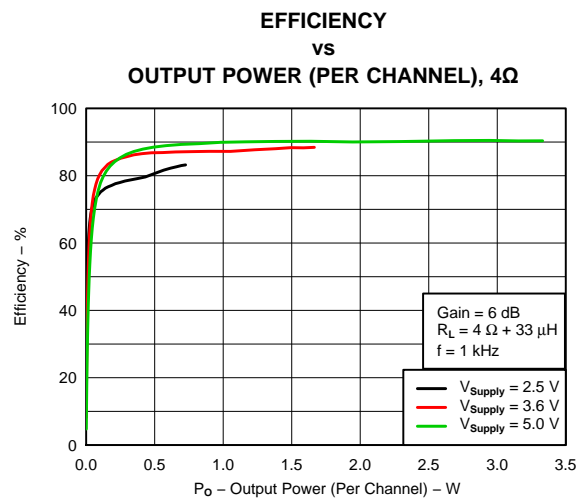


Figure 19.

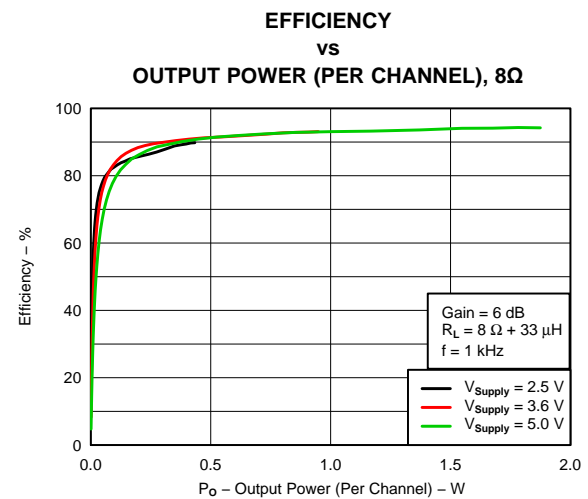


Figure 20.

**TOTAL POWER DISSIPATION
vs
TOTAL OUTPUT POWER, 4Ω**

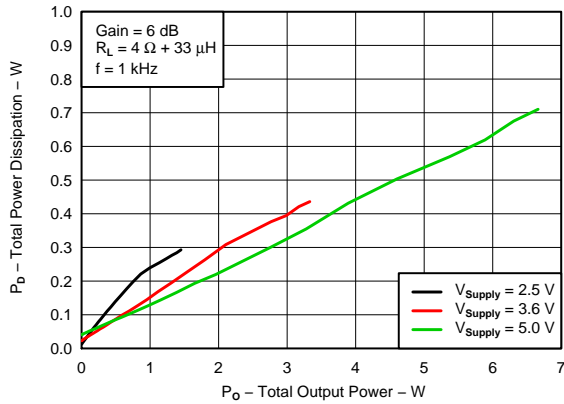


Figure 21.

**TOTAL POWER DISSIPATION
vs
TOTAL OUTPUT POWER, 8Ω**

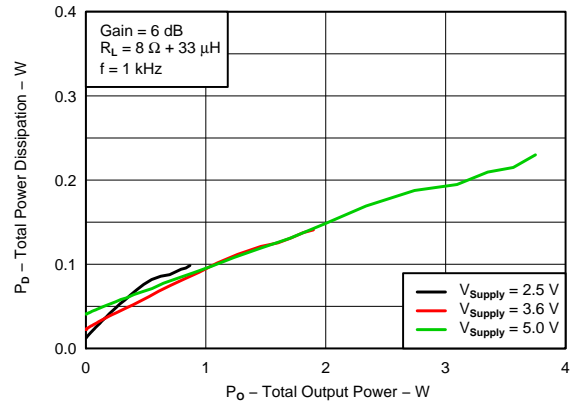


Figure 22.

**TOTAL SUPPLY CURRENT
vs
TOTAL OUTPUT POWER, 4Ω**

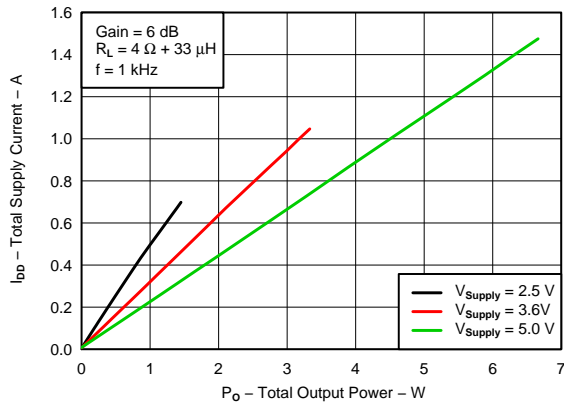


Figure 23.

**TOTAL SUPPLY CURRENT
vs
TOTAL OUTPUT POWER, 8Ω**

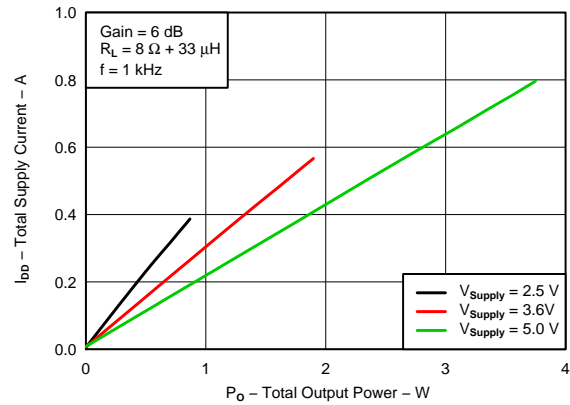


Figure 24.

**OUTPUT POWER
vs
SUPPLY VOLTAGE, 4Ω**

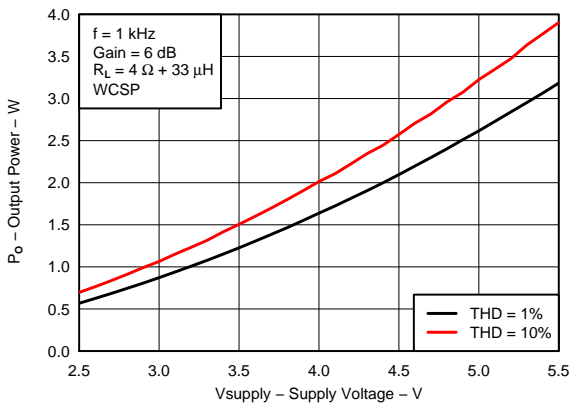


Figure 25.

**OUTPUT POWER
vs
SUPPLY VOLTAGE, 8Ω**

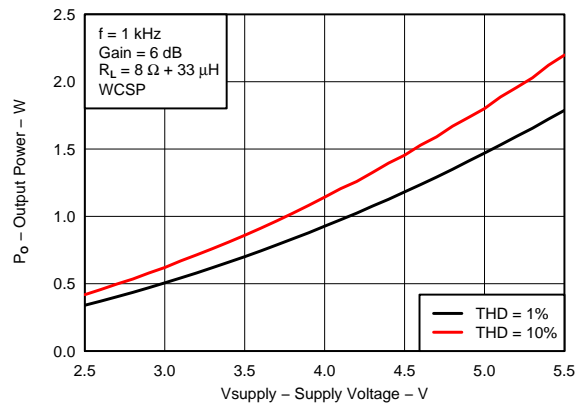


Figure 26.

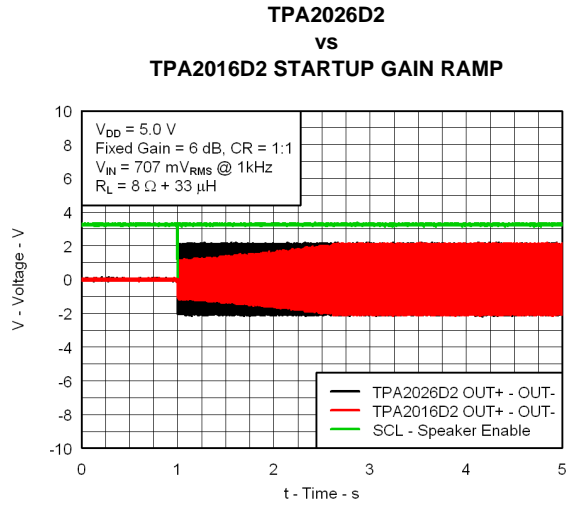


Figure 27.

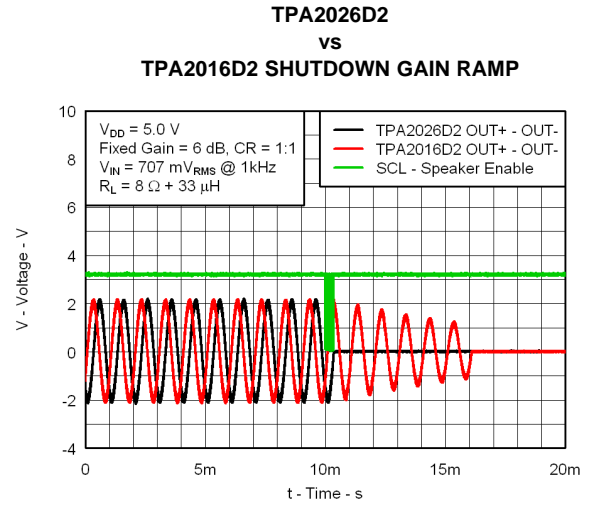


Figure 28.

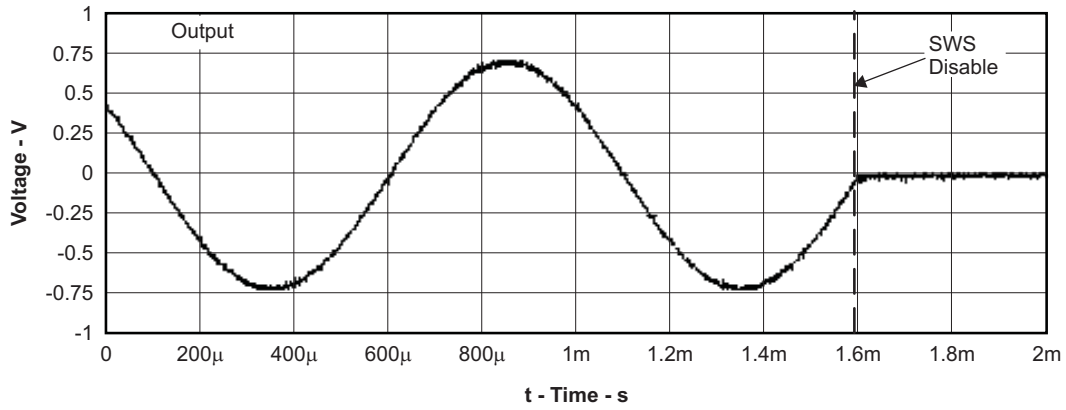


Figure 29. Shutdown Time

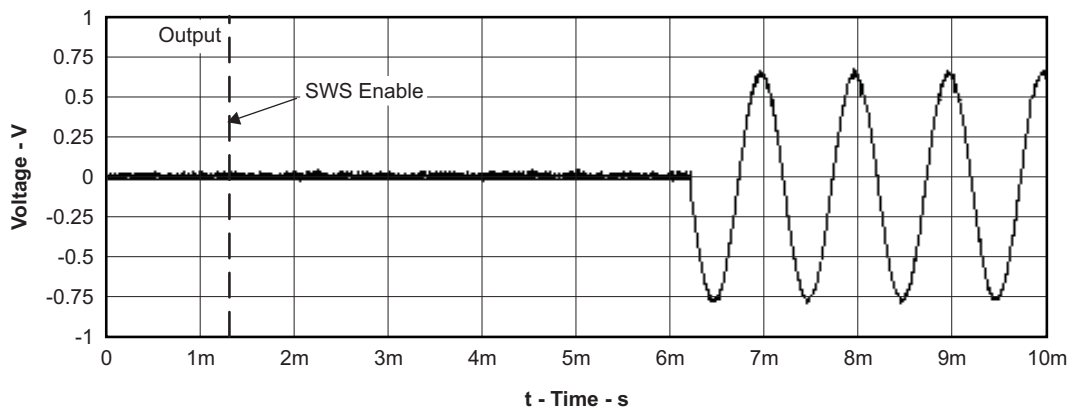


Figure 30. Startup Time

APPLICATION INFORMATION

AUTOMATIC GAIN CONTROL

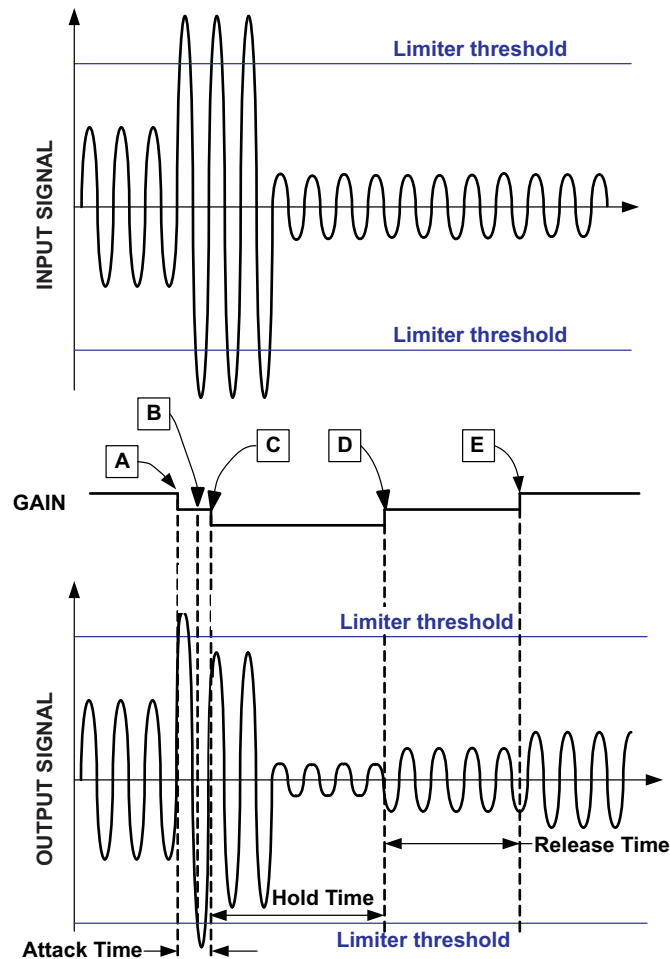
The Automatic Gain Control (AGC) feature provides continuous automatic gain adjustment to the amplifier through an internal PGA. This feature enhances the perceived audio loudness and at the same time prevents speaker damage from occurring (Limiter function).

The AGC function attempts to maintain the audio signal gain as selected by the user through the Fixed Gain, Limiter Level, and Compression Ratio variables. Other advanced features included are Maximum Gain and Noise Gate Threshold. [Table 1](#) describes the function of each variable in the AGC function.

Table 1. TPA2026D2 AGC Variable Descriptions

VARIABLE	DESCRIPTION
Maximum Gain	The gain at the lower end of the compression region.
Fixed Gain	The normal gain of the device when the AGC is inactive. The fixed gain is also the initial gain when the device comes out of shutdown mode or when the AGC is disabled.
Limiter Level	The value that sets the maximum allowed output amplitude.
Compression Ratio	The relation between input and output voltage.
Noise Gate Threshold	Below this value, the AGC holds the gain to prevent breathing effects.
Attack Time	The minimum time between two gain decrements.
Release Time	The minimum time between two gain increments.
Hold Time	The time it takes for the very first gain increment after the input signal amplitude decreases.

The AGC works by detecting the audio input envelope. The gain changes depending on the amplitude, the limiter level, the compression ratio, and the attack and release time. The gain changes constantly as the audio signal increases and/or decreases to create the compression effect. The gain step size for the AGC is 0.5 dB. If the audio signal has near-constant amplitude, the gain does not change. Figure 31 shows how the AGC works.



- A. Gain decreases with no delay; attack time is reset. Release time and hold time are reset.
- B. Signal amplitude above limiter level, but gain cannot change because attack time is not over.
- C. Attack time ends; gain is allowed to decrease from this point forward by one step. Gain decreases because the amplitude remains above limiter threshold. All times are reset
- D. Gain increases after release time finishes and signal amplitude remains below desired level. All times are reset after the gain increase.
- E. Gain increases after release time is finished again because signal amplitude remains below desired level. All times are reset after the gain increase.

Figure 31. Input and Output Audio Signal vs Time

Since the number of gain steps is limited the compression region is limited as well. The following figure shows how the gain changes vs. the input signal amplitude in the compression region.

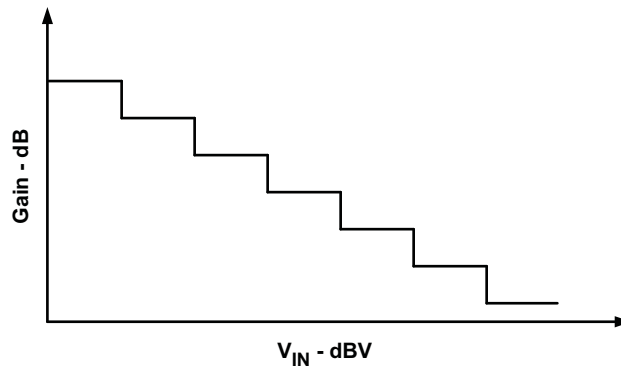


Figure 32. Input Signal Voltage vs Gain

Thus the AGC performs a mapping of the input signal vs. the output signal amplitude. This mapping can be modified according to the variables from [Table 1](#).

The following graphs and explanations show the effect of each variable to the AGC independently and which considerations should be taken when choosing values.

Fixed Gain: The fixed gain determines the initial gain of the AGC. Set the gain using the following variables:

- Set the fixed gain to be equal to the gain when the AGC is disabled.
- Set the fixed gain to maximize SNR.
- Set the fixed gain such that it will not overdrive the speaker.

[Figure 33](#) shows how the fixed gain influences the input signal amplitude vs. the output signal amplitude state diagram. The dotted 1:1 line is displayed for reference. The 1:1 line means that for a 1dB increase in the input signal, the output increases by 1dB.

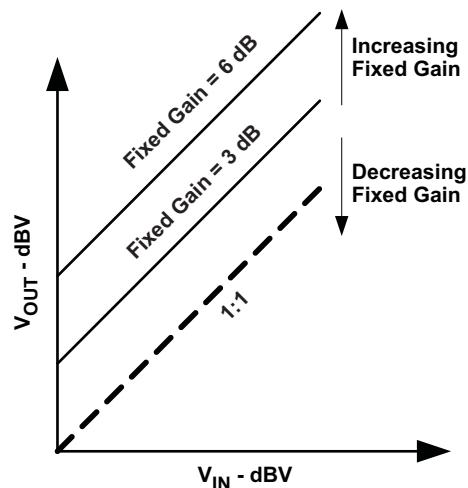


Figure 33. Output Signal vs Input Signal State Diagram Showing Different Fixed Gain Configurations

If the Compression function is enabled, the Fixed Gain is adjustable from -28dB to 30dB . If the Compression function is disabled, the Fixed gain is adjustable from 0dB to 30dB .

Limiter Level: The Limiter level sets the maximum amplitude allowed at the output of the amplifier. The limiter should be set with the following constraints in mind:

- Below or at the maximum power rating of the speaker
- Below the minimum supply voltage in order to avoid clipping

[Figure 34](#) shows how the limiter level influences the input signal amplitude vs. the output signal amplitude state diagram.

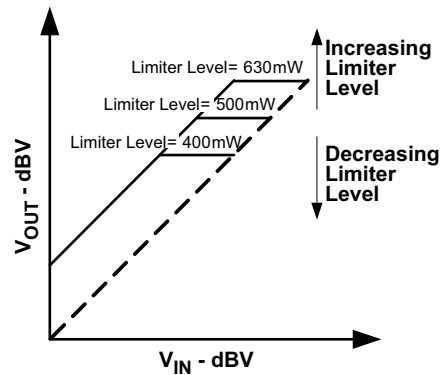


Figure 34. Output Signal vs Input Signal State Diagram Showing Different Limiter Level Configurations

The limiter level and the fixed gain influence each other. If the fixed gain is set high, the AGC has a large limiter range. The fixed gain is set low, the AGC has a short limiter range. Figure 35 illustrates the two examples:

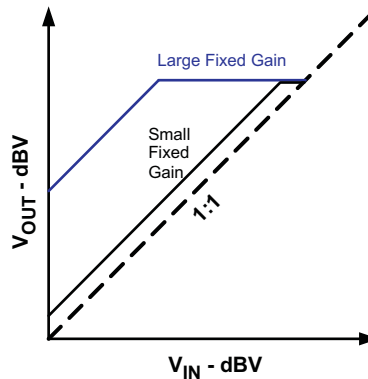


Figure 35. Output Signal vs Input Signal State Diagram Showing Same Limiter Level Configurations with Different Fixed Gain Configurations

Compression Ratio: The compression ratio sets the relation between input and output signal outside the limiter level region. The compression ratio compresses the dynamic range of the audio. For example if the audio source has a dynamic range of 60dB and compression ratio of 2:1 is selected, then the output has a dynamic range of 30dB. Most small form factor speakers have small dynamic range. Compression ratio allows audio with large dynamic range to fit into a speaker with small dynamic range.

The compression ratio also increases the loudness of the audio without increasing the peak voltage. The higher the compression ratio, the louder the perceived audio.

For example:

- A compression ratio of 4:1 is selected (meaning that a 4dB change in the input signal results in a 1dB signal change at the output)
- A fixed gain of 0dB is selected and the maximum audio level is at 0dBV.

When the input signal decreases to -32dBV, the amplifier increases the gain to 24dB in order to achieve an output of -8dBV. The output signal amplitude equation is:

$$\text{Output signal amplitude} = \frac{\text{Input signal initial amplitude} - |\text{Current input signal amplitude}|}{\text{Compression ratio}} \quad (1)$$

In this example:

$$-8\text{dBV} = \frac{0\text{dBV} - |-32\text{dBV}|}{4} \quad (2)$$

The gain change equation is:

$$\text{Gain change} = \left(1 - \frac{1}{\text{Compression ratio}} \right) \times \text{Input signal change} \quad (3)$$

$$24 \text{ dB} = \left(1 - \frac{1}{4} \right) \times 32 \quad (4)$$

Consider the following when setting the compression ratio:

- Dynamic range of the speaker
- Fixed gain level
- Limiter Level
- Audio Loudness vs Output Dynamic Range.

Figure 36 shows different settings for dynamic range and different fixed gain selected but no limiter level.

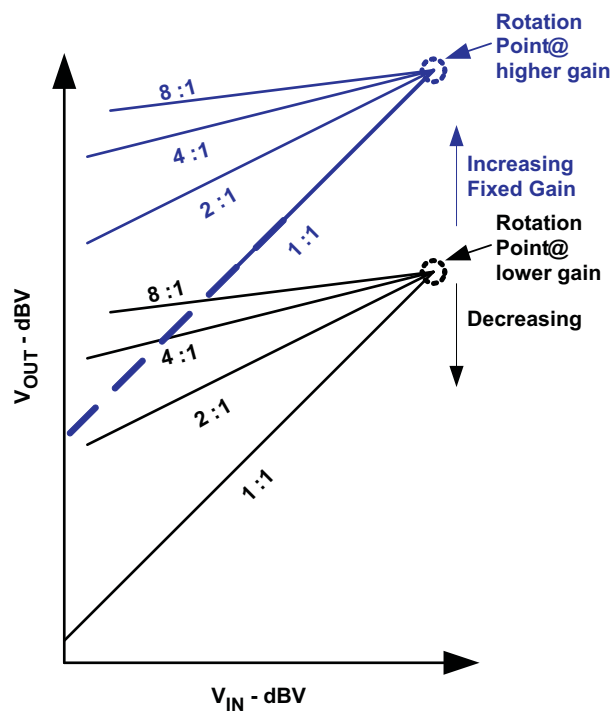


Figure 36. Output Signal vs Input Signal State Diagram Showing Different Compression Ratio Configurations with Different Fixed Gain Configurations

The rotation point is always at $V_{IN} = 10\text{dBV}$. The rotation point is not located at the intersection of the limiter region and the compression region. By changing the fixed gain the rotation point will move in the y-axis direction only, as shown in the previous graph.

Interaction Between Compression Ratio and Limiter Range: The compression ratio can be limited by the limiter range. Note that the limiter range is selected by the limiter level and the fixed gain.

For a setting with large limiter range, the amount of gain steps in the AGC remaining to perform compression are limited. Figure 37 shows two examples, where the fixed gain was changed.

1. Small limiter range yielding a large compression region (small fixed gain).
2. Large limiter range yielding a small compression region (large fixed gain).

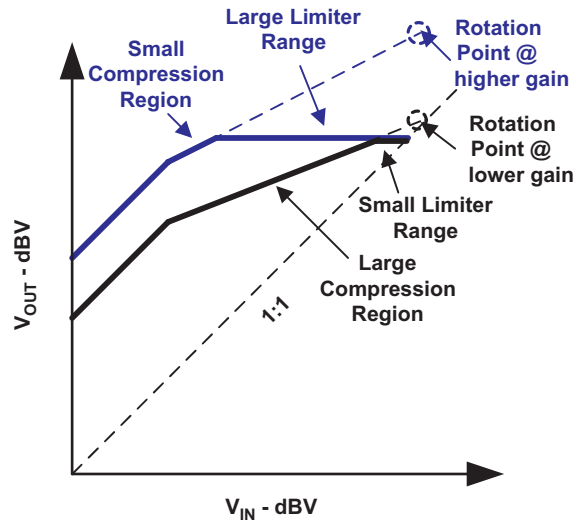


Figure 37. Output Signal vs Input Signal State Diagram Showing the Effects of the Limiter Range to the Compression Region

Noise Gate Threshold: The noise gate threshold prevents the AGC from changing the gain when there is no audio at the input of the amplifier. The noise gate threshold stops gain changes until the input signal is above the noise gate threshold. Select the noise gate threshold to be above the noise but below the minimum audio at the input of the amplifier signal. A filter is needed between delta-sigma CODEC/DAC and TPA2026D2 for effectiveness of the noise gate function. The filter eliminates the out-of-band noise from delta-sigma modulation and keeps the CODEC/DAC output noise lower than the noise gate threshold.

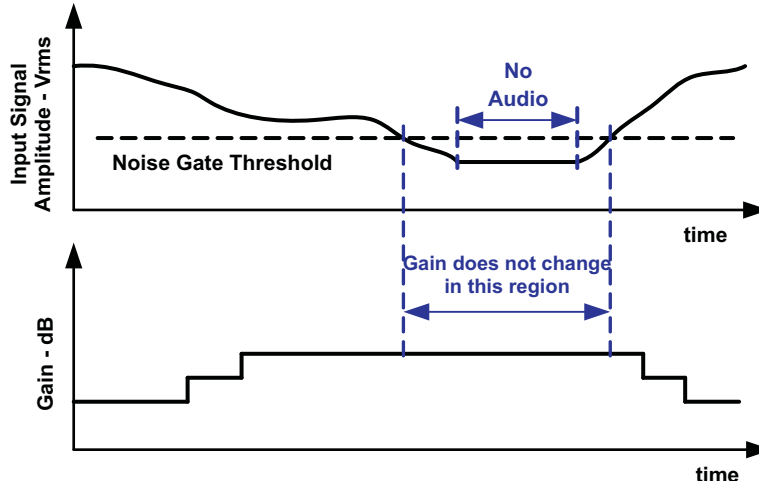


Figure 38. Time Diagram Showing the Relationship Between Input Signal Amplitude, Noise Gate Threshold, and Gain Versus Time

Maximum Gain: This variable limits the number of gain steps in the AGC. This feature is useful in order to accomplish a more advanced output signal vs. input signal transfer characteristic.

For example, to prevent the gain from going above a certain value, reduce the maximum gain.

However, this variable will affect the limiter range and the compression region. If the maximum gain is decreased, the limiter range and/or compression region is reduced. Figure 39 illustrates the effects.

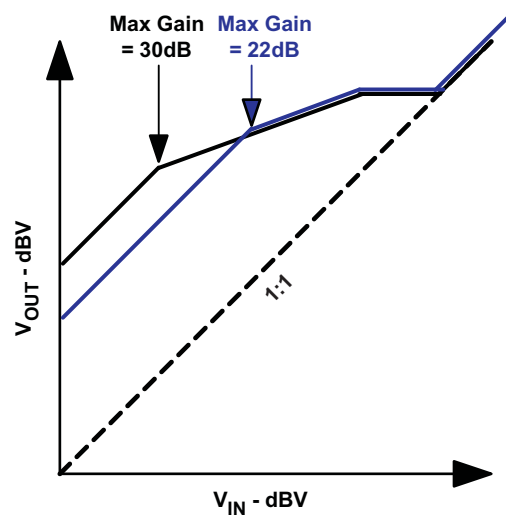


Figure 39. Output Signal vs Input Signal State Diagram Showing Different Maximum Gains

A particular application requiring maximum gain of 22dB, for example. Thus, set the maximum gain at 22dB. The amplifier gain will never have a gain higher than 22dB; however, this will reduce the limiter range.

Attack, Release, and Hold Time:

- The attack time is the minimum time between gain decreases.
- The release time is the minimum time between gain increases.
- The hold time is the minimum time between a gain decrease (attack) and a gain increase (release). The hold time can be deactivated. Hold time is only valid if greater than release time.

Successive gain decreases are never faster than the attack time. Successive gain increases are never faster than the release time.

All time variables (attack, release and hold) start counting after each gain change performed by the AGC. The AGC is allowed to decrease the gain (attack) only after the attack time finishes. The AGC is allowed to increase the gain (release) only after the release time finishes counting. However, if the preceding gain change was an attack (gain increase) and the hold time is enabled and longer than the release time, then the gain is only increased after the hold time.

The hold time is only enabled after a gain decrease (attack). The hold time replaces the release time after a gain decrease (attack). If the gain needs to be increased further, then the release time is used. The release time is used instead of the hold time if the hold time is disabled.

The attack time should be at least 100 times shorter than the release and hold time. The hold time should be the same or greater than the release time. It is important to select reasonable values for those variables in order to prevent the gain from changing too often or too slow.

Figure 40 illustrates the relationship between the three time variables.

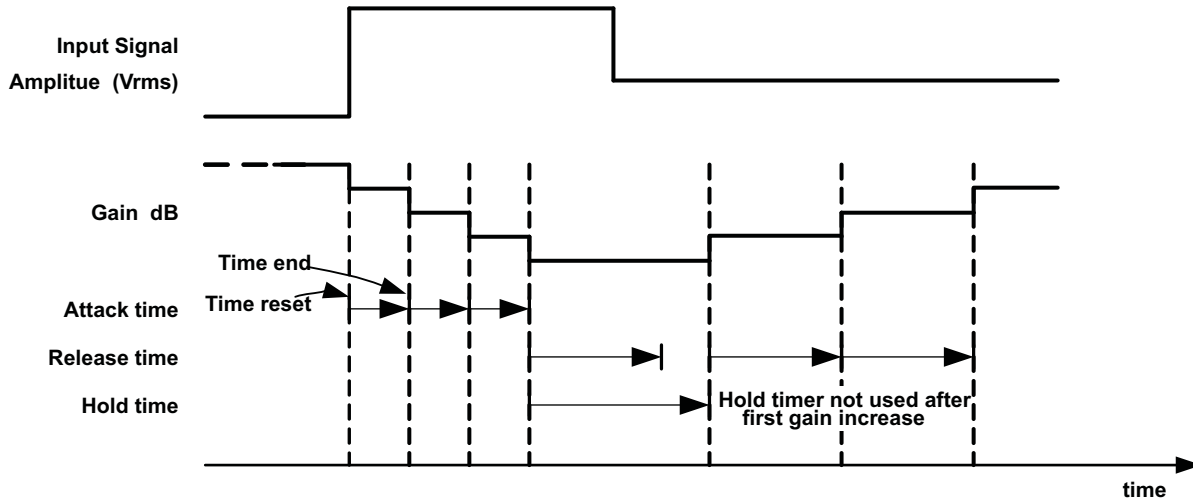


Figure 40. Time Diagram Showing the Relation Between the Attack, Release, and Hold Time vs Input Signal Amplitude and Gain

Figure 41 shows a state diagram of the input signal amplitude vs. the output signal amplitude and a summary of how the variables from Table 1 described in the preceding pages affect them.

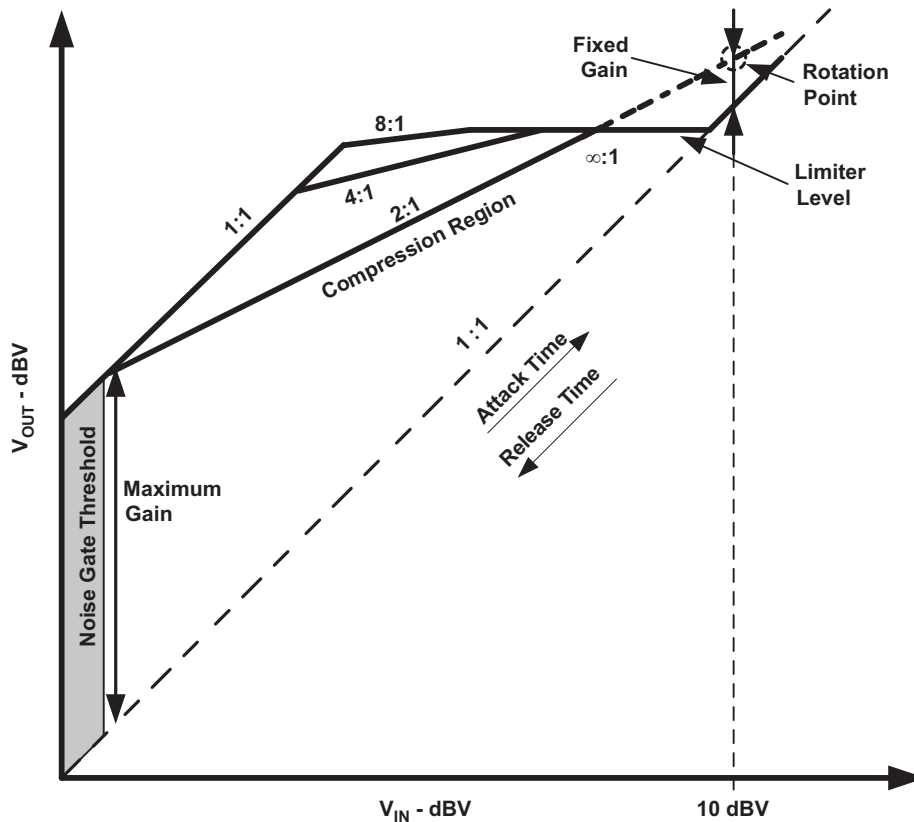


Figure 41. Output Signal vs Input Signal State Diagram

TPA2026D2 AGC OPERATION

The TPA2026D2 is controlled by the I²C interface. The correct start-up sequence is:

1. Apply the supply voltage to the AV_{DD} and PV_{DD} (L, R) pins.
2. Apply a voltage above V_{IH} to the SDZ pin. The TPA2026D2 powers up the I²C interface and the control logic. By default, the device is in active mode (SWS = 0). After 5 ms the amplifier will enable the class-D output stage and become fully operational.

AGC STARTUP CONDITION

The amplifier gain at start-up depends on the following conditions:

1. Start-up from hardware reset (EN from 0 to 1): The amplifier starts up immediately at default fixed gain. AGC starts controlling gain once the input audio signal exceeds noise gate threshold.
2. Start-up from software shutdown (SWS from 1 to 0): The amplifier starts up immediately at the latest fixed gain during software shutdown, regardless the attack/ release time. For example:
 - Audio is playing at fixed gain 6dB
 - Devices goes to software shutdown (SWS = 1)
 - Set fixed gain from 6 dB to 12 dB
 - Remove software shutdown (SWS = 0)
 - Amplifier starts up immediately at 12 dB
3. During audio playback with AGC on, gain changes according to attack/ release time. For example:
 - Audio is playing at fixed gain 6 dB and 1:1 compression ratio
 - Set fixed gain from 6 dB to 12 dB, at release time 500 ms / 6 dB
 - Amplifier will take 500 ms to ramp from 6 dB to 12 dB
4. When SPKR_EN_R = 0, SPKR_EN_L = 0 and SWS = 0, the amplifier is set at fixed gain. The amplifier will start up at fixed gain when either SPKR_EN_R and SPKR_EN_L transitions from 0 to 1.

CAUTION

Do not interrupt the start-up sequence after changing SDZ from V_{IL} to V_{IH}.

Do not interrupt the start-up sequence after changing SWS from 1 to 0.

The default conditions of TPA2026D2 allows audio playback without I²C control. Refer to [Table 4](#) for the entire default conditions.

There are several options to disable the amplifier:

- Write SPK_EN_R = 0 and SPK_EN_L = 0 to the register (0x01, 6 and 0x01, 7). This write disables each speaker amplifier, but leaves all other circuits operating.
- Write SWS = 1 to the register (0x01, 5). This action disables most of the amplifier functions.
- Apply V_{IL} to SDZ. This action shuts down all the circuits and has very low quiescent current consumption. This action resets the registers to its default values.

CAUTION

Do not interrupt the shutdown sequence after changing SDZ from V_{IH} to V_{IL}.

Do not interrupt the shutdown sequence after changing SWS from 0 to 1.

TPA2026D2 AGC RECOMMENDED SETTINGS

Table 2. Recommended AGC Settings for Different Types of Audio Source ($V_{DD} = 3.6\text{ V}$)

AUDIO SOURCE	COMPRESSION RATIO	ATTACK TIME (ms/6 dB)	RELEASE TIME (ms/6 dB)	HOLD TIME (ms)	FIXED GAIN (dB)	LIMITER LEVEL (dBV)
Pop Music	4:1	1.28 to 3.84	986 to 1640	137	6	7.5
Classical	2:1	2.56	1150	137	6	8
Jazz	2:1	5.12 to 10.2	3288	—	6	8
Rap/Hip Hop	4:1	1.28 to 3.84	1640	—	6	7.5
Rock	2:1	3.84	4110	—	6	8
Voice/News	4:1	2.56	1640	—	6	8.5

GENERAL I²C OPERATION

The I²C bus employs two signals, SDA (data) and SCL (clock), to communicate between integrated circuits in a system. The bus transfers data serially one bit at a time. The address and data 8-bit bytes are transferred most significant bit (MSB) first. In addition, each byte transferred on the bus is acknowledged by the receiving device with an *acknowledge* bit. Each transfer operation begins with the master device driving a start condition on the bus and ends with the master device driving a stop condition on the bus. The bus uses transitions on the data terminal (SDA) while the clock is at logic high to indicate start and stop conditions. A high-to-low transition on SDA indicates a start and a low-to-high transition indicates a stop. Normal data-bit transitions must occur within the low time of the clock period. Figure 42 shows a typical sequence. The master generates the 7-bit slave address and the read/write (R/W) bit to open communication with another device, and then waits for an acknowledge condition. The TPA2026D2 holds SDA low during the acknowledge clock period to indicate acknowledgment. When this acknowledgment occurs, the master transmits the next byte of the sequence. Each device is addressed by a unique 7-bit slave address plus R/W bit (1 byte). All compatible devices share the same signals via a bidirectional bus using a wired-AND connection.

An external pull-up resistor must be used for the SDA and SCL signals to set the logic high level for the bus. When the bus level is 5 V, use pull-up resistors between 1 k Ω and 2 k Ω .

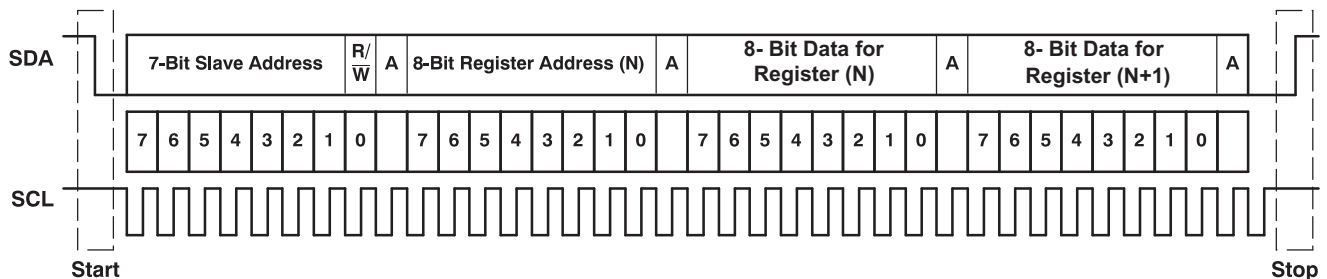


Figure 42. Typical I²C Sequence

There is no limit on the number of bytes that can be transmitted between start and stop conditions. When the last word transfers, the master generates a stop condition to release the bus. A generic data transfer sequence is shown in Figure 42.

SINGLE-AND MULTIPLE-BYTE TRANSFERS

The serial control interface supports both single-byte and multi-byte read/write operations for all registers.

During multiple-byte read operations, the TPA2026D2 responds with data, one byte at a time, starting at the register assigned, as long as the master device continues to respond with acknowledgments.

The TPA2026D2 supports sequential I²C addressing. For write transactions, if a register is issued followed by data for that register and all the remaining registers that follow, a sequential I²C write transaction has occurred. For I²C sequential write transactions, the register issued then serves as the starting point, and the amount of data subsequently transmitted, before a stop or start is transmitted, determines the number of registers written.

SINGLE-BYTE WRITE

As Figure 43 shows, a single-byte data write transfer begins with the master device transmitting a start condition followed by the I²C device address and the read/write bit. The read/write bit determines the direction of the data transfer. For a write data transfer, the read/write bit must be set to '0'. After receiving the correct I²C device address and the read/write bit, the TPA2026D2 responds with an acknowledge bit. Next, the master transmits the register byte corresponding to the TPA2026D2 internal memory address being accessed. After receiving the register byte, the TPA2026D2 again responds with an acknowledge bit. Next, the master device transmits the data byte to be written to the memory address being accessed. After receiving the register byte, the TPA2026D2 again responds with an acknowledge bit. Finally, the master device transmits a stop condition to complete the single-byte data write transfer.

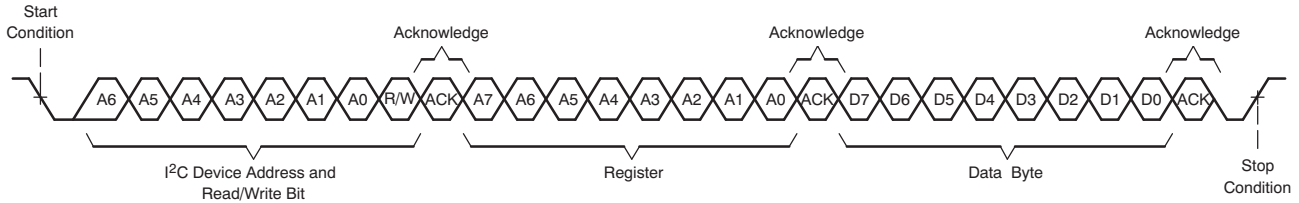


Figure 43. Single-Byte Write Transfer

MULTIPLE-BYTE WRITE AND INCREMENTAL MULTIPLE-BYTE WRITE

A multiple-byte data write transfer is identical to a single-byte data write transfer except that multiple data bytes are transmitted by the master device to the TPA2026D2 as shown in Figure 44. After receiving each data byte, the TPA2026D2 responds with an acknowledge bit.

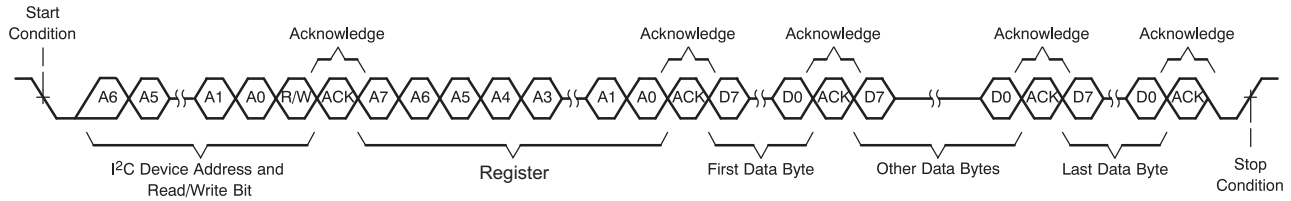


Figure 44. Multiple-Byte Write Transfer

SINGLE-BYTE READ

As Figure 45 shows, a single-byte data read transfer begins with the master device transmitting a start condition followed by the I²C device address and the read/write bit. For the data read transfer, both a write followed by a read are actually executed. Initially, a write is executed to transfer the address byte of the internal memory address to be read. As a result, the read/write bit is set to a '0'.

After receiving the TPA2026D2 address and the read/write bit, the TPA2026D2 responds with an acknowledge bit. The master then sends the internal memory address byte, after which the TPA2026D2 issues an acknowledge bit. The master device transmits another start condition followed by the TPA2026D2 address and the read/write bit again. This time the read/write bit is set to '1', indicating a read transfer. Next, the TPA2026D2 transmits the data byte from the memory address being read. After receiving the data byte, the master device transmits a *not-acknowledge* followed by a stop condition to complete the single-byte data read transfer.

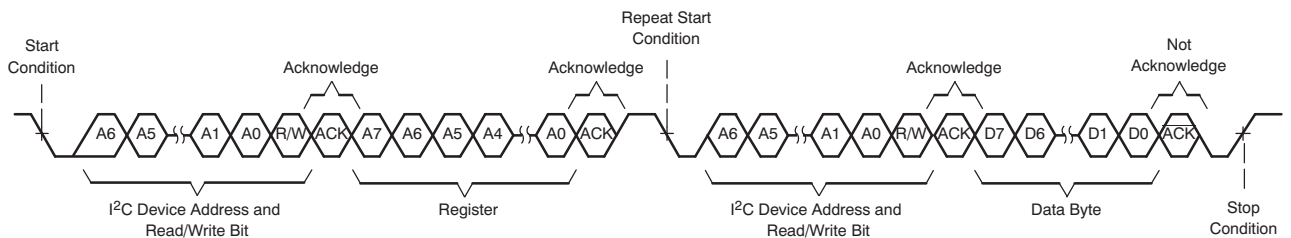


Figure 45. Single-Byte Read Transfer

MULTIPLE-BYTE READ

A multiple-byte data read transfer is identical to a single-byte data read transfer except that multiple data bytes are transmitted by the TPA2026D2 to the master device as shown in Figure 46. With the exception of the last data byte, the master device responds with an acknowledge bit after receiving each data byte.

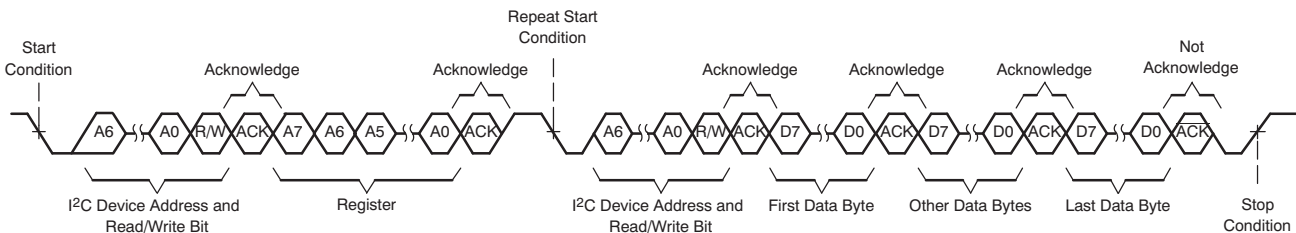


Figure 46. Multiple-Byte Read Transfer

Register Map

Table 3. TPA2026D2 Register Map

REGISTER	Bit7	Bit6	Bit5	Bit4	Bit3	Bit2	Bit1	Bit0
1	SPK_EN_R	SPL_EN_L	SWS	FAULT_R	FAULT_L	Thermal	1	NG_EN
2	0	0	ATK_time [5]	ATK_time [4]	ATK_time [3]	ATK_time [2]	ATK_time [1]	ATK_time [0]
3	0	0	REL_time [5]	REL_time [4]	REL_time [3]	REL_time [2]	REL_time [1]	REL_time [0]
4	0	0	Hold_time [5]	Hold_time [4]	Hold_tme [3]	Hold_time [2]	Hold_time [1]	Hold_time [0]
5	0	0	FixedGain [5]	FixedGain [4]	FixedGain [3]	FixedGain [2]	FixedGain [1]	FixedGain [0]
6	Output Limiter Disable	NoiseGate Threshold [1]	NoiseGate Threshold [2]	Output Limiter Level [4]	Output Limiter Level [3]	Output Limiter Level [2]	Output Limiter Level [1]	Output Limiter Level [0]
7	Max Gain [3]	Max Gain [2]	Max Gain [1]	Max Gain [0]	0	0	Compression Ratio [1]	Compression Ratio [0]

The default register map values are given in [Table 4](#).

Table 4. TPA2026D2 Default Register Values

REGISTER	0x01	0x02	0x03	0x04	0x05	0x06	0x07
Default	C3h	05h	0Bh	00h	06h	3Ah	C2h

Any register above address 0x08 is reserved for testing and should not be written to because it may change the function of the device. If read, these bits may assume any value.

Some of the default values can be reprogrammed through the I²C interface and written to the EEPROM. This function is useful to speed up the turn-on time of the device and minimizes the number of I²C writes. If this is required, contact your local TI representative.

The TPA2026D2 I²C address is 0xB0 (binary 10110000) for writing and 0xB1 (binary 10110001) for reading. If a different I²C address is required, contact your local TI representative. See the general I²C operation section for more details.

The following tables show the details of the registers, the default values, and the values that can be programmed through the I²C interface.

IC FUNCTION CONTROL (Address: 1)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION
01 (01 _H) – IC Function Control	7	SPK_EN_R	1 (enabled)	Enables right amplifier
	6	SPK_EN_L	1 (enabled)	Enables left amplifier
	5	SWS	0 (enabled)	Shutdown IC when bit = 1
	4	FAULT_R	0	Changes to a 1 when there is a short on the right channel. Reset by writing a 0.
	3	FAULT_L	0	Changes to a 1 when there is a short on the left channel. Reset by writing a 0
	2	Thermal	0	Changes to a 1 when die temperature is above 150°C
	1	UNUSED	1	
	0	NG_EN	1 (enabled)	Enables Noise Gate function

- SPK_EN_R:** Enable bit for the right-channel amplifier. Amplifier is active when bit is high. This function is gated by thermal and returns once the IC is below the threshold temperature.
- SPK_EN_L:** Enable bit for the left-channel amplifier. Amplifier is active when bit is high. This function is gated by thermal and returns once the IC is below the threshold temperature
- SWS:** Software shutdown control. The device is in software shutdown when the bit is '1' (control, bias and oscillator are inactive). When the bit is '0' the control, bias and oscillator are enabled.
- FAULT_L:** This bit indicates that an over-current event has occurred on the left channel with a '1'. This bit is cleared by writing a '0' to it.
- FAULT_R:** This bit indicates that an over-current event has occurred on the right channel with a '1'. This bit is cleared by writing a '0' to it.
- Thermal:** This bit indicates a thermal shutdown that was initiated by the hardware with a '1'. This bit is deglitched and latched, and can be cleared by writing a '0' to it.
- NG_EN:** Enable bit for the Noise Gate function. This function is enabled when this bit is high. This function can only be enabled when the Compression ratio is not 1:1.

AGC ATTACK CONTROL (Address: 2)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION			
02 (02 _H) – AGC Control	7:6	Unused	00				
	5:0	ATK_time	000101 (1.28 ms/6 dB)	AGC Attack time (gain ramp down)			
				Per Step	Per 6 dB	90% Range	
				000001	0.1067 ms	1.28 ms	5.76 ms
				000010	0.2134 ms	2.56 ms	11.52 ms
				000011	0.3201 ms	3.84 ms	17.19 ms
				000100	0.4268 ms	5.12 ms	23.04 ms
				(time increases by 0.1067 ms with every step)			
111111	6.722 ms	80.66 ms	362.99 ms				

- ATK_time** These bits set the attack time for the AGC function. The attack time is the minimum time between gain decreases.

AGC RELEASE CONTROL (Address: 3)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION			
03 (03 _H) – AGC Release Control	7:6	Unused	00				
	5:0	REL_time	001011 (0.9864 sec/6 dB)	AGC Release time (gain ramp down)			
					Per Step	Per 6 dB	90% Range
				000001	0.0137 s	0.1644 s	0.7398 s
				000010	0.0274 s	0.3288 s	1.4796 s
				000011	0.0411 s	0.4932 s	2.2194 s
				000100	0.0548 s	0.6576 s	2.9592 s
				(time increases by 0.0137 s with every step)			
111111	0.8631 s	10.36 s	46.6 s				

REL_time These bits set the release time for the AGC function. The release time is the minimum time between gain increases.

AGC HOLD TIME CONTROL (Address: 4)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION			
04 (04 _H) – AGC Hold Time Control	7:6	Unused	00				
	5:0	Hold_time	000000 (disabled)	AGC Hold time			
					Per Step		
				000000	Hold Time Disable		
				000001	0.0137 s		
				000010	0.0274 s		
				000011	0.0411 s		
				000100	0.0548 s		
(time increases by 0.0137 s with every step)							
111111	0.8631 s						

Hold_time These bits set the hold time for the AGC function. The hold time is the minimum time between a gain decrease (attack) and a gain increase (release). The hold time can be deactivated.

AGC FIXED GAIN CONTROL (Address: 5)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION	
05 (05 _H) – AGC Fixed Gain Control	7:6	Unused	00		
	5:0	Fixed Gain	000110 (6 dB)	Sets the fixed gain of the amplifier: two's complement	
					Gain
				100100	–28 dB
				100101	–27 dB
				100110	–26 dB
				(gain increases by 1 dB with every step)	
				111101	–3 dB
				111110	–2 dB
				111111	–1 dB
				000000	0 dB
				000001	1 dB
				000010	2 dB
				000011	3 dB
				(gain increases by 1dB with every step)	
				011100	28 dB
011101	29 dB				
011110	30 dB				

Fixed Gain These bits are used to select the fixed gain of the amplifier. If compression is enabled, fixed gain is adjustable from –28dB to 30dB. If compression is disabled, fixed gain is adjustable from 0dB to 30dB.

AGC CONTROL (Address: 6)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION			
06 (06 _H) – AGC Control	7	Output Limiter Disable	0 (enable)	Disables the output limiter function. Can only be disabled when the AGC compression ratio is 1:1 (off)			
	6:5	NoiseGate Threshold	01 (4 mV _{rms})	Select the threshold of the noise gate			
					Threshold		
				00	1 mV _{rms}		
				01	4 mV _{rms}		
				10	10 mV _{rms}		
	4:0	Output Limiter Level	11010 (6.5 dBV)	Selects the output limiter level			
					Output Power (Wrms)	Peak Output Voltage (Vp)	dBV
				00000	0.03	0.67	–6.5
				00001	0.03	0.71	–6
				00010	0.04	0.75	–5.5
				(Limiter level increases by 0.5dB with every step)			
				11101	0.79	3.55	8
11110				0.88	3.76	8.5	
11111	0.99	3.99	9				

Output Limiter Disable This bit disables the output limiter function when set to 1. Can only be disabled when the AGC compression ratio is 1:1

NoiseGate Threshold These bits set the threshold level of the noise gate. NoiseGate Threshold is only functional when the compression ratio is not 1:1

Output Limiter Level These bits select the output limiter level. Output Power numbers are for 8Ω load.

AGC CONTROL (Address: 7)

REGISTER ADDRESS	I ² C BIT	LABEL	DEFAULT	DESCRIPTION	
07 (07 _H) – AGC Control	7:4	Max Gain	1100 (30 dB)	Selects the maximum gain the AGC can achieve	
					Gain
				0000	18 dB
				0001	19 dB
				0010	20 dB
		(gain increases by 1 dB with every step)			
		1100	30 dB		
	3:2	Unused	00		
	1:0	Compression Ratio	10 (4:1)	Selects the compression ratio of the AGC	
					Ratio
00				1:1 (off)	
01				2:1	
10				4:1	
	11	8:1			

Compression Ratio These bits select the compression ratio. Output Limiter is enabled by default when the compression ratio is not 1:1.

Max Gain These bits select the maximum gain of the amplifier. In order to maximize the use of the AGC, set the Max Gain to 30dB

DECOUPLING CAPACITOR C_S

The TPA2026D2 is a high-performance Class-D audio amplifier that requires adequate power supply decoupling to ensure the efficiency is high and total harmonic distortion (THD) is low. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) 1- μ F ceramic capacitor (typically) placed as close as possible to the device PVDD (L, R) lead works best. Placing this decoupling capacitor close to the TPA2026D2 is important for the efficiency of the Class-D amplifier, because any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency. For filtering lower-frequency noise signals, a 4.7 μ F or greater capacitor placed near the audio power amplifier would also help, but it is not required in most applications because of the high PSRR of this device.

INPUT CAPACITORS C_I

The input capacitors and input resistors form a high-pass filter with the corner frequency, f_C , determined in [Equation 5](#).

$$f_C = \frac{1}{(2\pi \times R_I \times C_I)} \quad (5)$$

The value of the input capacitor is important to consider as it directly affects the bass (low frequency) performance of the circuit. Speakers in wireless phones cannot usually respond well to low frequencies, so the corner frequency can be set to block low frequencies in this application. Not using input capacitors can increase output offset. [Equation 6](#) is used to solve for the input coupling capacitance. If the corner frequency is within the audio band, the capacitors should have a tolerance of $\pm 10\%$ or better, because any mismatch in capacitance causes an impedance mismatch at the corner frequency and below.

$$C_I = \frac{1}{(2\pi \times R_I \times f_C)} \quad (6)$$

YZH PACKAGE DIMENSIONS

The package dimensions for this YZH package are shown in the table below. See the package drawing at the end of this data sheet for more details.

Packaged Devices	D	E
TPA2026D2YZH	Max = 2160 μ m	Max = 2137 μ m
	Min = 2100 μ m	Min = 2077 μ m

BOARD LAYOUT

In making the pad size for the WCSP balls, it is recommended that the layout use non solder mask defined (NSMD) land. With this method, the solder mask opening is made larger than the desired land area, and the opening size is defined by the copper pad width. [Figure 47](#) and [Table 5](#) show the appropriate diameters for a WCSP layout. The TPA2026D2 evaluation module (EVM) layout is shown in the next section as a layout example.

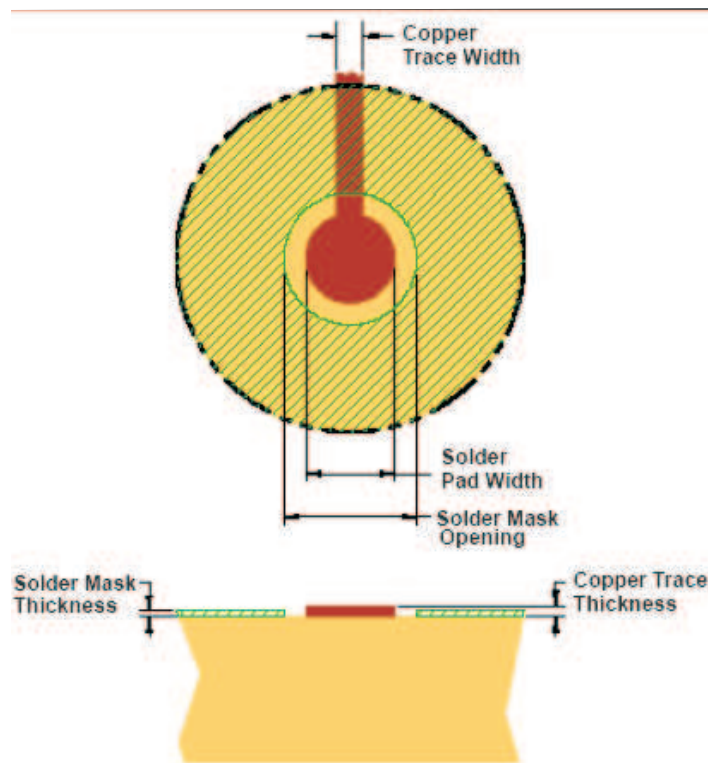


Figure 47. Land Pattern Dimensions

Table 5. Land Pattern Dimensions^{(1) (2) (3) (4)}

SOLDER PAD DEFINITIONS	COPPER PAD	SOLDER MASK ⁽⁵⁾ OPENING	COPPER THICKNESS	STENCIL ^{(6) (7)} OPENING	STENCIL THICKNESS
Non solder mask defined (NSMD)	275 μm (+0.0, -25 μm)	375 μm (+0.0, -25 μm)	1 oz max (32 μm)	275 μm \times 275 μm Sq. (rounded corners)	125 μm thick

- (1) Circuit traces from NSMD defined PWB lands should be 75 μm to 100 μm wide in the exposed area inside the solder mask opening. Wider trace widths reduce device stand off and impact reliability.
- (2) Best reliability results are achieved when the PWB laminate glass transition temperature is above the operating the range of the intended application.
- (3) Recommend solder paste is Type 3 or Type 4.
- (4) For a PWB using a Ni/Au surface finish, the gold thickness should be less 0.5 μm to avoid a reduction in thermal fatigue performance.
- (5) Solder mask thickness should be less than 20 μm on top of the copper circuit pattern
- (6) Best solder stencil performance is achieved using laser cut stencils with electro polishing. Use of chemically etched stencils results in inferior solder paste volume control.
- (7) Trace routing away from WCSP device should be balanced in X and Y directions to avoid unintentional component movement due to solder wetting forces.

COMPONENT LOCATION

Place all external components very close to the TPA2026D2. Placing the decoupling capacitor, C_S , close to the TPA2026D2 is important for the efficiency of the Class-D amplifier. Any resistance or inductance in the trace between the device and the capacitor can cause a loss in efficiency.

TRACE WIDTH

Recommended trace width at the solder balls is 75 μm to 100 μm to prevent solder wicking onto wider PCB traces. For high current pins (PVDD (L, R), PGND, and audio output pins) of the TPA2026D2, use 100- μm trace widths at the solder balls and at least 500- μm PCB traces to ensure proper performance and output power for the device. For the remaining signals of the TPA2026D2, use 75- μm to 100- μm trace widths at the solder balls. The audio input pins (INR \pm and INL \pm) must run side-by-side to maximize common-mode noise cancellation.

EFFICIENCY AND THERMAL INFORMATION

The maximum ambient temperature depends on the heat-sinking ability of the PCB system. The derating factor for the package is shown in the dissipation rating table. Converting this to θ_{JA} for the WCSP package:

$$\theta_{JA} = \frac{1}{\text{Derating Factor}} = \frac{1}{0.01} = 100^{\circ}\text{C/W} \quad (7)$$

Given θ_{JA} of 100°C/W , the maximum allowable junction temperature of 150°C , and the maximum internal dissipation of 0.4 W (0.2 W per channel) for 1.5 W per channel, 8- Ω load, 5-V supply, from [Figure 15](#), the maximum ambient temperature can be calculated with the following equation.

$$T_{A\text{Max}} = T_{J\text{Max}} - \theta_{JA} P_{D\text{MAX}} = 150 - 100 (0.4) = 110^{\circ}\text{C} \quad (8)$$

[Equation 8](#) shows that the calculated maximum ambient temperature is 110°C at maximum power dissipation with a 5-V supply and 8- Ω a load. The TPA2026D2 is designed with thermal protection that turns the device off when the junction temperature surpasses 150°C to prevent damage to the IC. Also, using speakers more resistive than 8- Ω dramatically increases the thermal performance by reducing the output current and increasing the efficiency of the amplifier.

OPERATION WITH DACS AND CODECS

In using Class-D amplifiers with CODECs and DACs, sometimes there is an increase in the output noise floor from the audio amplifier. This occurs when output frequencies of the CODEC/DAC mix with the Class-D switching frequency and create sum/difference components in the audio band. The noise increase can be solved by placing an RC low-pass filter between the CODEC/DAC and audio amplifier. The filter reduces high frequencies that cause the problem and allows proper performance.

SHORT CIRCUIT AUTO-RECOVERY

When a short circuit event happens, the TPA2026D2 goes to low duty cycle mode and tries to reactivate itself every 110 μs . This auto-recovery will continue until the short circuit event stops. This feature can protect the device without affecting the device's long term reliability. FAULT bit (register 1, bit 3) still requires a write to clear.

FILTER FREE OPERATION AND FERRITE BEAD FILTERS

A ferrite bead filter can often be used if the design is failing radiated emissions without an LC filter and the frequency sensitive circuit is greater than 1 MHz. This filter functions well for circuits that just have to pass FCC and CE because FCC and CE only test radiated emissions greater than 30 MHz. When choosing a ferrite bead, choose one with high impedance at high frequencies, and low impedance at low frequencies. In addition, select a ferrite bead with adequate current rating to prevent distortion of the output signal.

Use an LC output filter if there are low frequency (< 1 MHz) EMI sensitive circuits and/or there are long leads from amplifier to speaker. [Figure 48](#) shows typical ferrite bead and LC output filters.

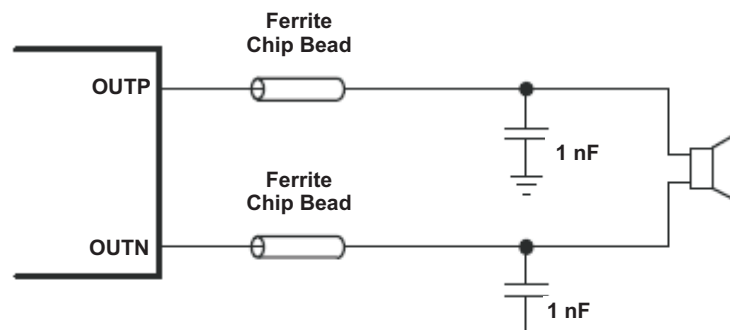


Figure 48. Typical Ferrite Bead Filter (Chip bead example: TDK: MPZ1608S221A)

REVISION HISTORY

Changes from Original (March 2010) to Revision A	Page
<ul style="list-style-type: none"> • Changed the Default values in Table 4 26 • Changed the Default value of the IC Function Control Table (I²C BIT 0) From: 0 (disabled) To: 1 (enabled) 27 	

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
TPA2026D2YZHR	ACTIVE	DSBGA	YZH	16	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	NSV	Samples
TPA2026D2YZHT	ACTIVE	DSBGA	YZH	16	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	NSV	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPA2026D2YZHR	DSBGA	YZH	16	3000	180.0	8.4	2.35	2.35	0.81	4.0	8.0	Q1
TPA2026D2YZHT	DSBGA	YZH	16	250	180.0	8.4	2.35	2.35	0.81	4.0	8.0	Q1

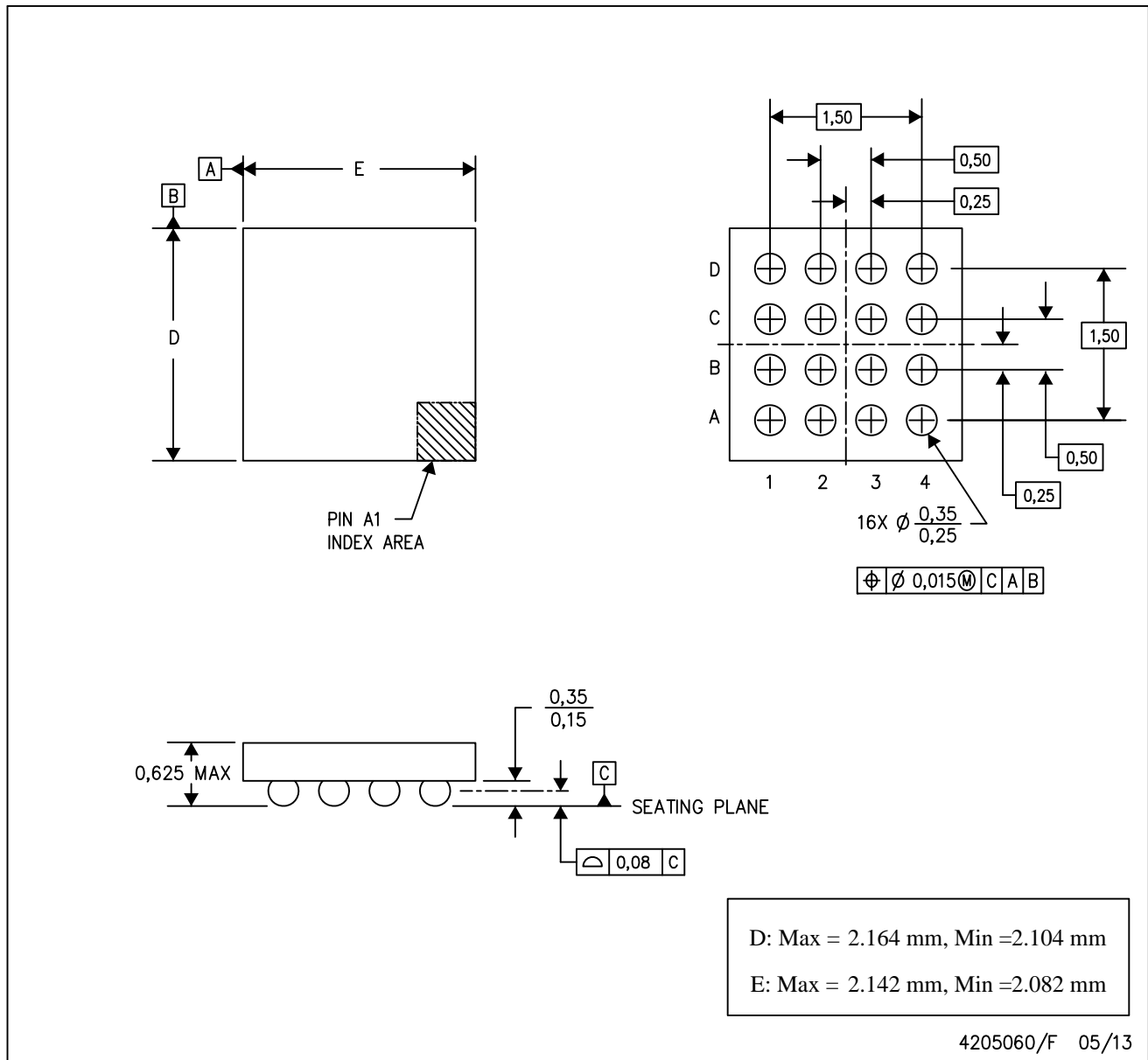
TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPA2026D2YZHR	DSBGA	YZH	16	3000	210.0	185.0	35.0
TPA2026D2YZHT	DSBGA	YZH	16	250	210.0	185.0	35.0

YZH (S-XBGA-N16)

DIE-SIZE BALL GRID ARRAY



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products

Audio	www.ti.com/audio
Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DLP® Products	www.dlp.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
OMAP Applications Processors	www.ti.com/omap
Wireless Connectivity	www.ti.com/wirelessconnectivity

Applications

Automotive and Transportation	www.ti.com/automotive
Communications and Telecom	www.ti.com/communications
Computers and Peripherals	www.ti.com/computers
Consumer Electronics	www.ti.com/consumer-apps
Energy and Lighting	www.ti.com/energy
Industrial	www.ti.com/industrial
Medical	www.ti.com/medical
Security	www.ti.com/security
Space, Avionics and Defense	www.ti.com/space-avionics-defense
Video and Imaging	www.ti.com/video

TI E2E Community

e2e.ti.com